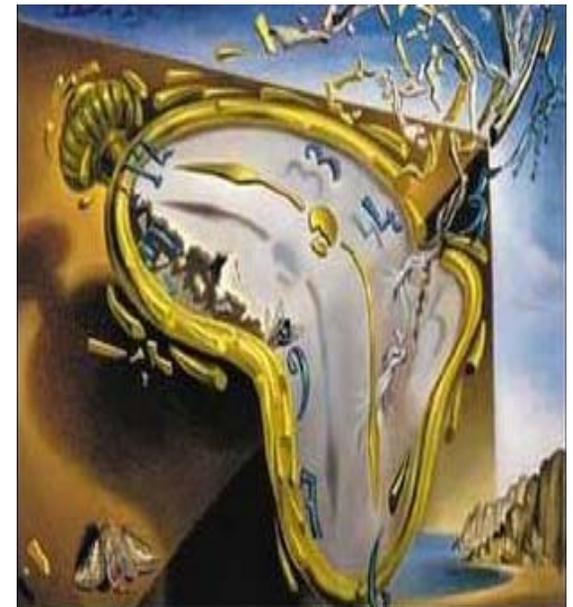


Nonlinear Analog Behavioral Modeling of Microwave Devices and Circuits

Dr. David E. Root
Principle Research Scientist
High Frequency Technology Center
Agilent Technologies
Santa Rosa, CA

IEEE MTT-S DML Lecture #1
Bergen, Norway
May 7, 2010



Acknowledgement

Norway IEEE MTT/AP Chapter

Yngve Thodesen

Karl-Martin Gjertsen

Marius Ubostad

Jonny Langmyren

Peter Myhrberg

Bjorn Birkeland

Riccardo Giacometti

Giovanni Damore

Key Contributors

Loren Betts

Alex Cognata

Chad Gillease

Daniel Gunyan

Jason Horn

Masaya Iwamoto

Greg Jue

Dominique Schreurs

David Sharrit

Nick Tufillaro

Jan Verspecht

Jianjun Xu

John Wood

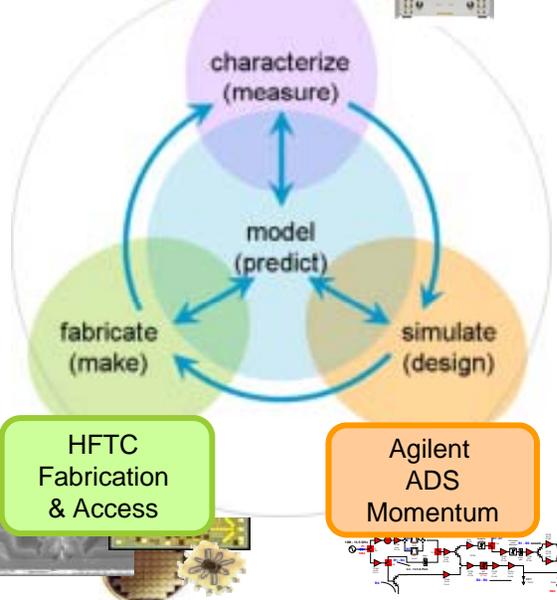
Agilent Management

Many others

Agilent High Frequency Technology Center

Measurement and Modeling Sciences

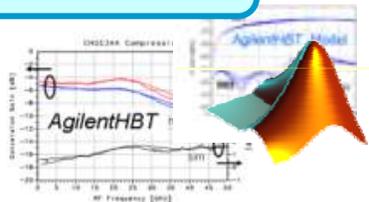
Agilent Measurement HW & SW IP



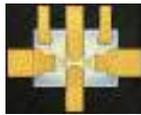
HFTC Fabrication & Access

Agilent ADS Momentum

HFTC Model & Measurement IP
analytical empirical behavioral



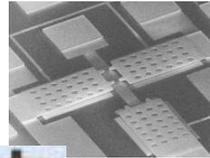
Integrated Diodes



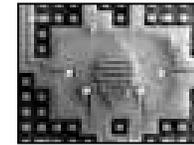
Hyperabrupt Diodes



MEMS



Liquid metal switches



Internal and external technology

GaN

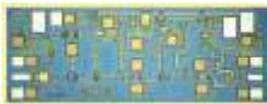
GaAs

InP

Diodes

Thin Film

pHEMT & FET ICs



HBT ICs



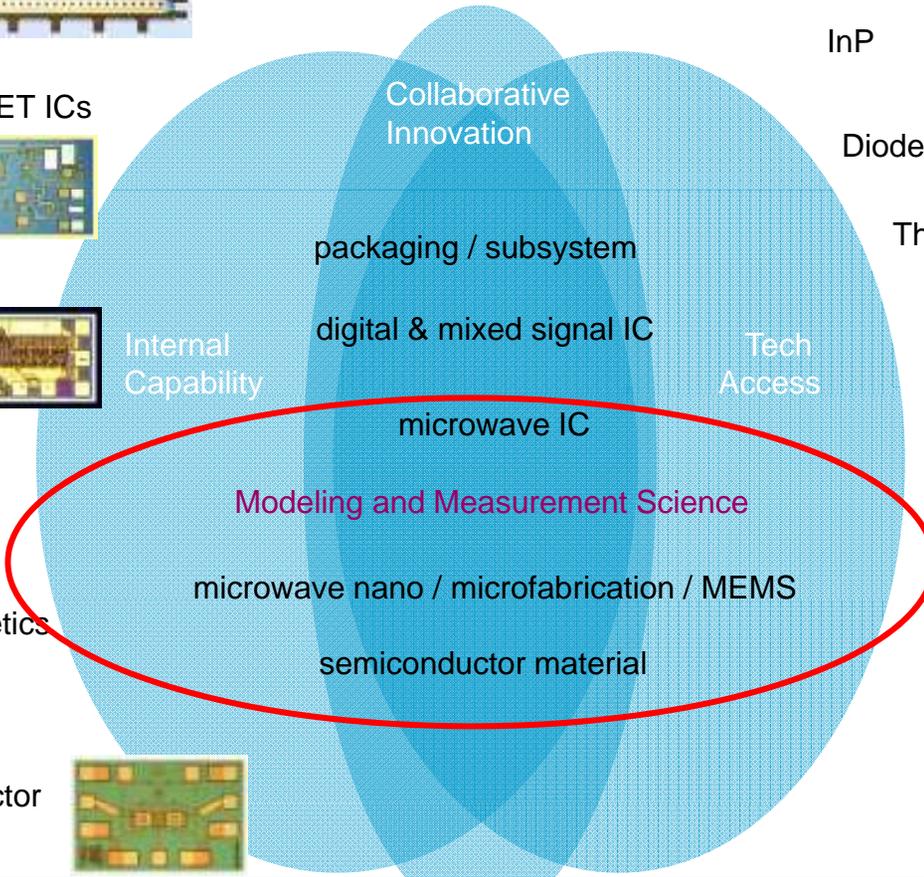
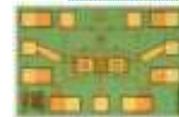
Thin Film



Ferromagnetics



Semiconductor switches



Outline

Introduction: Behavioral Models and NVNA

Functional Block Models

- Nonlinear Time Series
- X-parameters (PHD Model) in the Frequency Domain
- Mixed Time-Frequency Methods

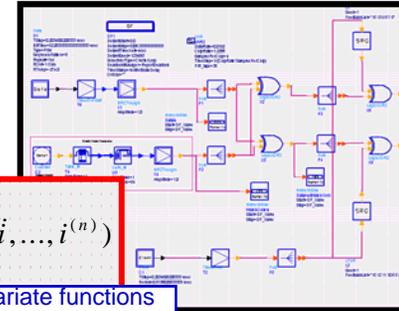
Summary and Conclusions

Introduction: Behavioral Modeling and Design Hierarchy

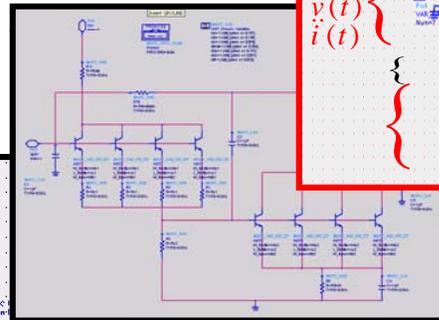
Top-down: system design
and specifications

Increasing model complexity

System



Circuit



$$y(t) : \quad i = f(v, v, \dots, i, \dots, i^{(n)})$$

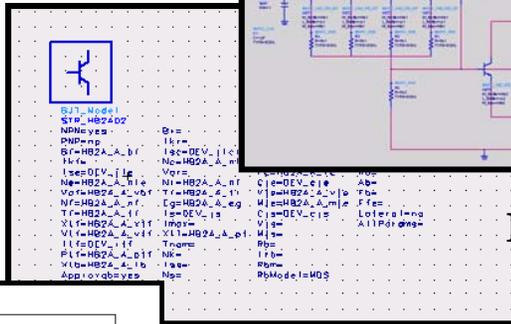
$\left. \begin{matrix} \dot{v}(t) \\ \ddot{v}(t) \\ \dot{i}(t) \end{matrix} \right\}$

Multivariate functions
for i_1, i_2

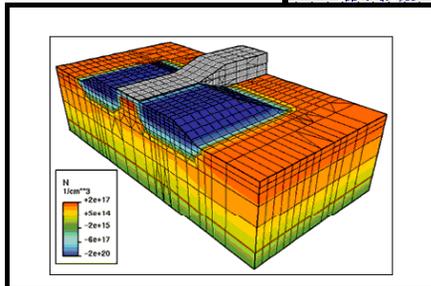
Embedding
Variables

Behavioral Model:
Accurate model of
lower level component
for simulation at next
highest level

Device



Equivalent Circuit Model
"Compact Model"

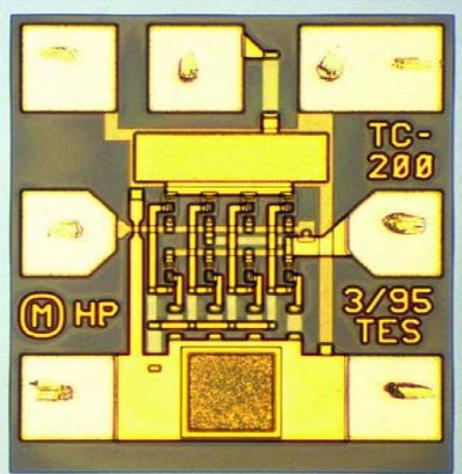


Increasing circuit/system complexity

Bottom up: verification

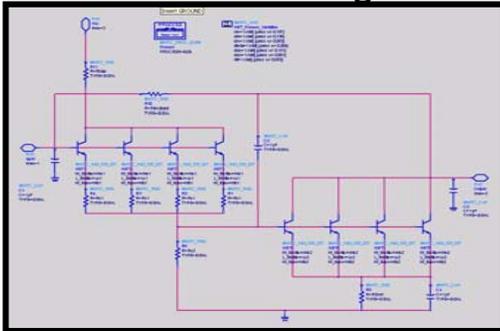
Measurement-Based and Simulation-Based Models

Actual Circuit



Amplifier or Mixer IC

DC-20 GHz HBT Agilent HMMC 5200 amp [2]



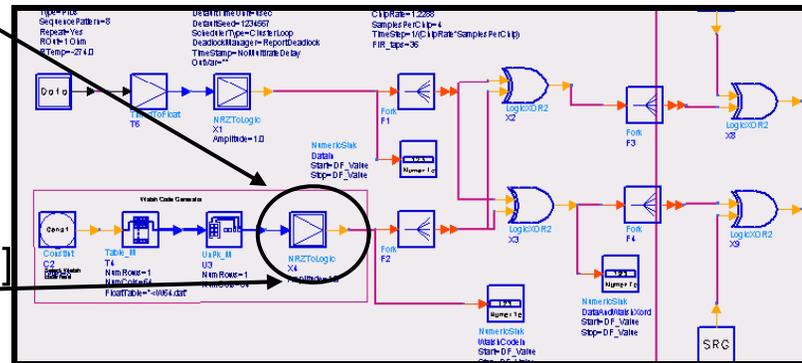
Detailed Circuit Model (SPICE/ADS) of IC

Measurement-Based Model

- Ckt. model may not exist
- Ckt. models may be inaccurate
- Completely protect design IP

Design of Module or Instrument Front End

Generate Behavioral Model



Simulation-Based Model

- Simulation speedup
- Design system before building/buying IC
- Completely protect design IP

Simple for Linear Ckts: S-parameters

S-parameters as simplest behavioral model

- Easy to measure at high frequencies
 - measure voltage traveling waves with a (linear) vector network analyzer (VNA)
 - don't need shorts/opens which can cause devices to oscillate or self-destruct
- Relate to familiar measurements (gain, loss, reflection coefficient ...)
- Can cascade S-parameters of multiple devices to predict system performance
- Can import and use S-parameter files in electronic-simulation tools (e.g. ADS)
- **BUT: No harmonics, No distortion, No nonlinearities, ...**
 Invalid for nonlinear devices excited by large signals, despite *ad hoc* attempts

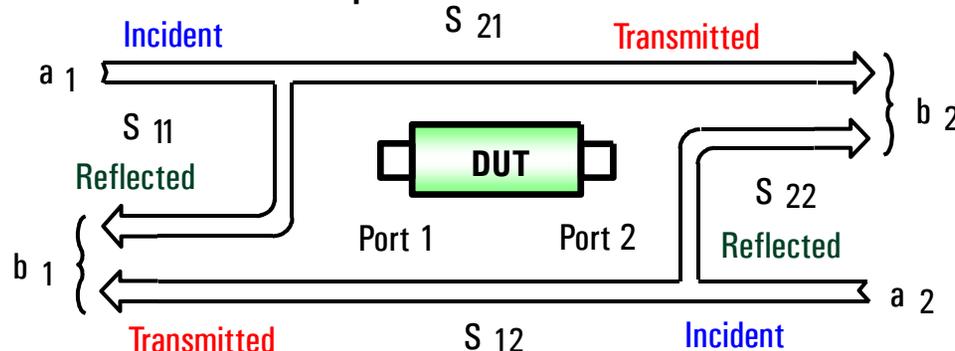
Linear Simulation:
Matrix Multiplication

S-parameters

$$b_1 = S_{11}a_1 + S_{12}a_2$$

$$b_2 = S_{21}a_1 + S_{22}a_2$$

Measure with linear VNA:
Small amplitude sinusoids



Model
Parameters:
Simple algebra

$$S_{ij} = \frac{b_i}{a_j} \Big|_{\substack{a_k=0 \\ k \neq j}}$$

Three Components of Behavioral Modeling

1. Model Formulation

- Nonlinear ODEs in Time Domain (e.g. Transient Analysis; all others)
- NL Spectral Map in Freq. Domain (e.g. Harmonic Balance) X-params
- Mixed Domains (e.g. ODE-Coupled Envelopes in Circuit Env. Analysis)

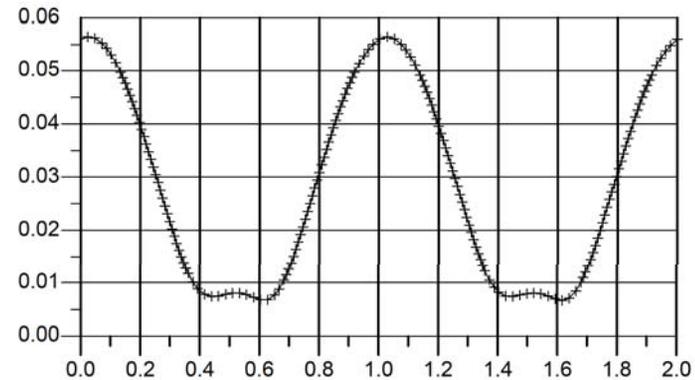
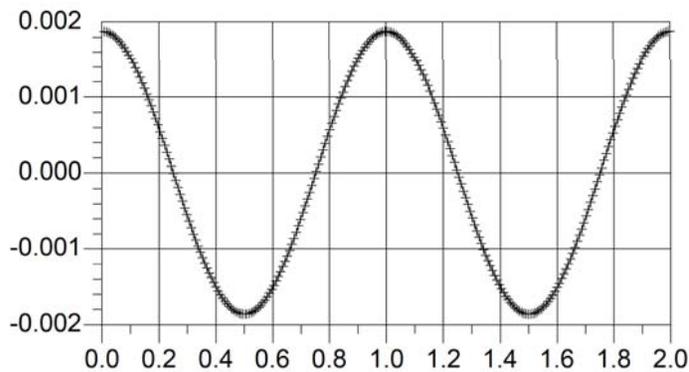
2. Experiment Design

- Stimulus needed to excite relevant dynamics

3. Model Identification

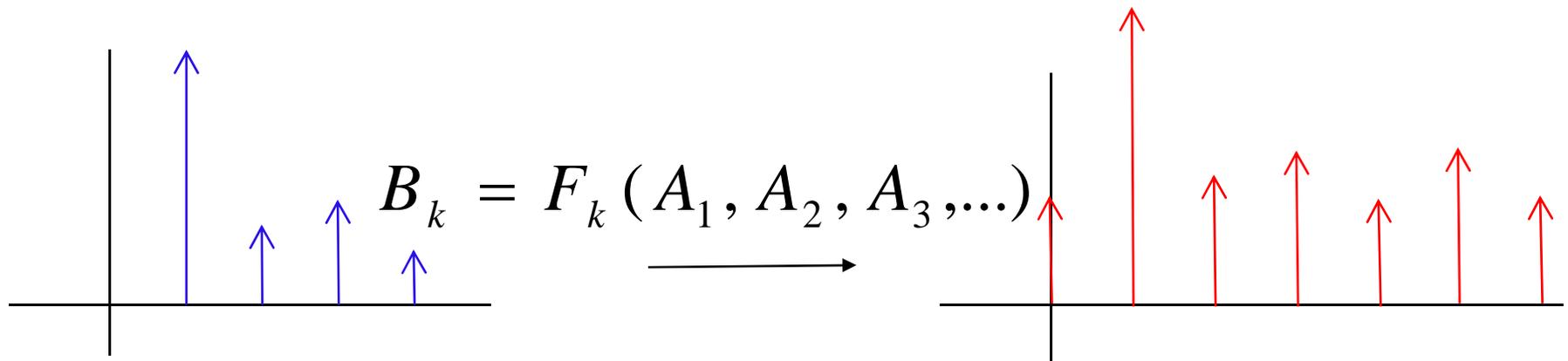
- Procedure to determine model “parameters”

Model Formulation: Time & Freq. Domains [1,6]



$$I(t) = F(V(t), \dot{V}(t), \ddot{V}(t), \dots, \dot{I}(t), \dots)$$

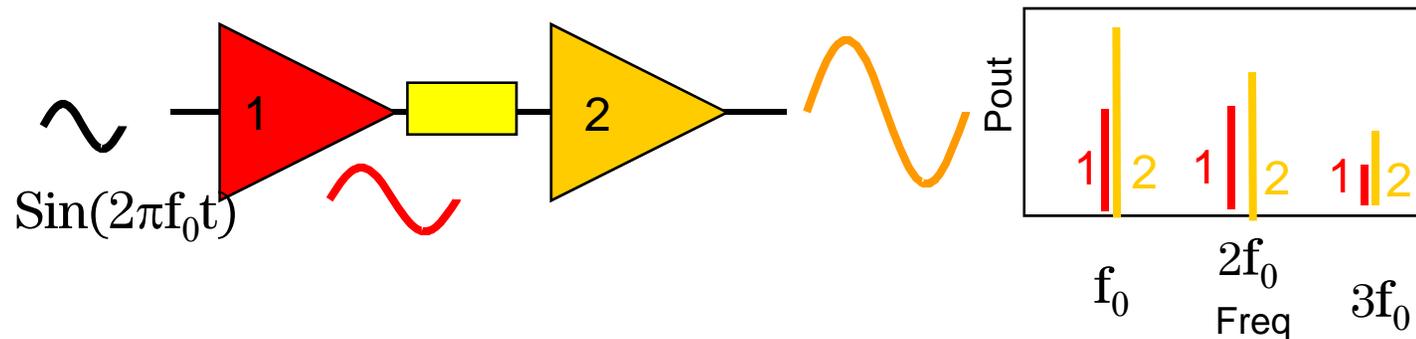
Natural for strongly nonlinear low-order (lumped) systems



Freq. Domain natural for low-distortion, high-freq. ICs

Formulate model eqs. in language native to appropriate simulator

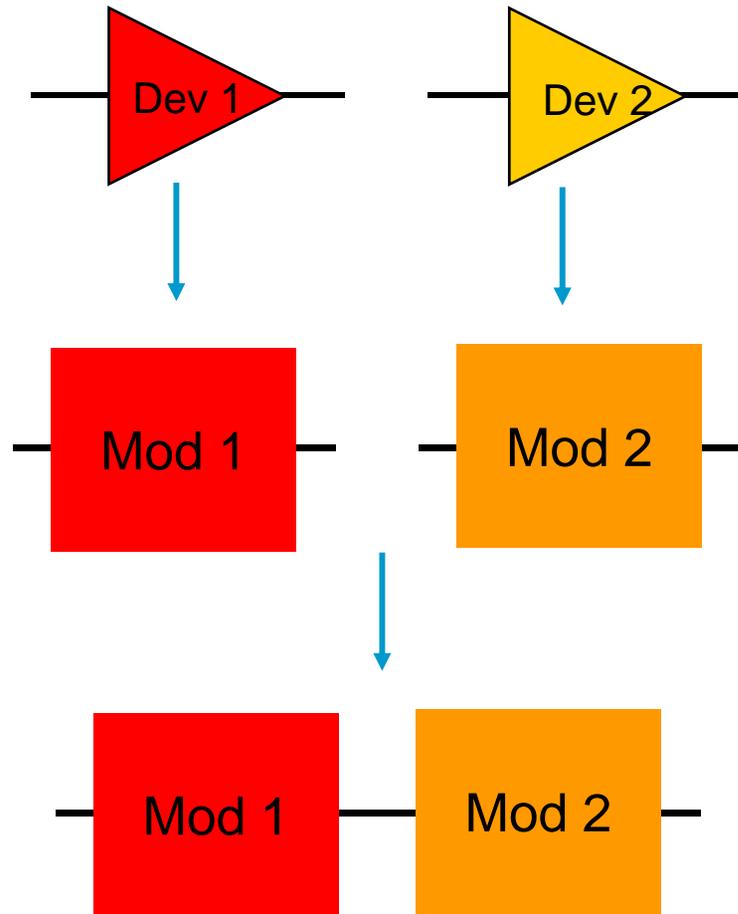
Wanted: Cascadability of *Nonlinear Components*



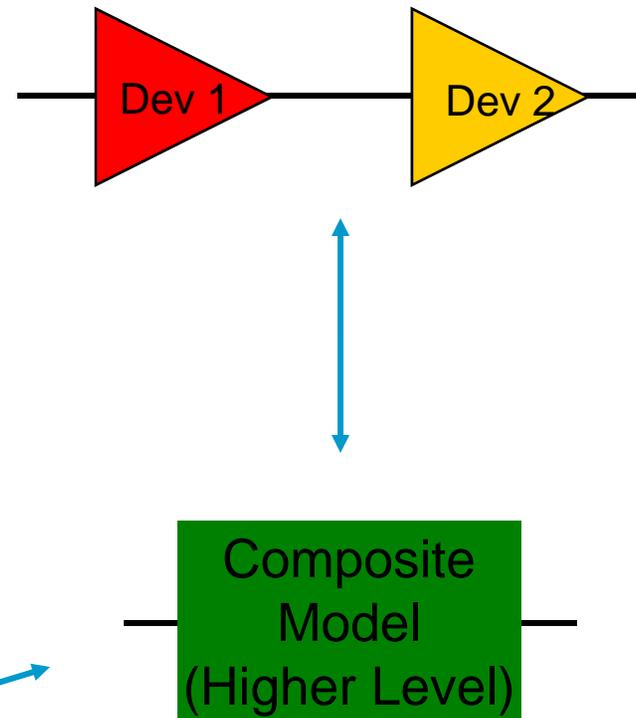
Predict signal and harmonics (magnitude and phase) through chains of *cascaded* nonlinear components under drive

- Inter-stage mismatch is important to final results
 - Can not infer these effects from VNA measurements (even “Hot S_{22} ”)
- Required for communication circuits and module design
- **Linear S-parameter theory doesn't apply!**
Most previous attempts to generalize S-parameters to nonlinear case are wrong!

Wanted: Hierarchical Modeling



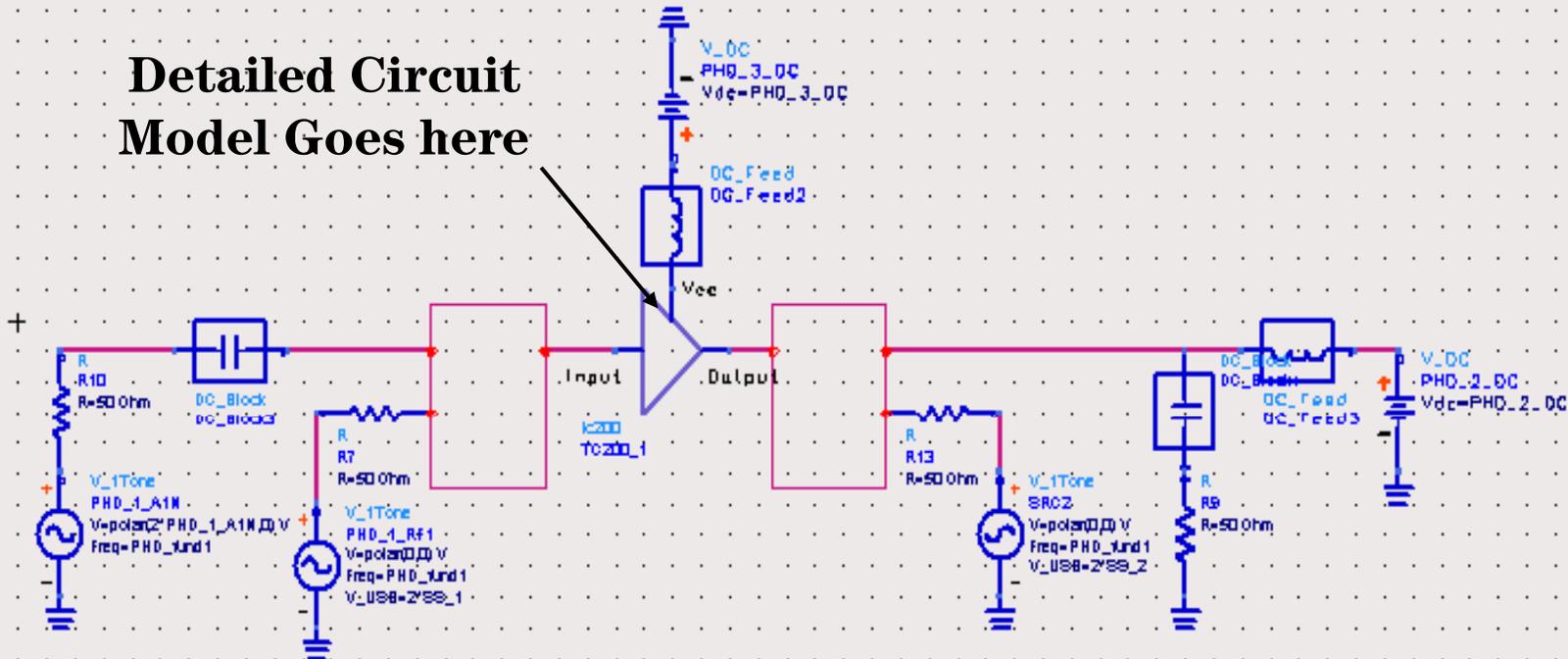
Model the cascade directly



A cascade of many models *reduced to one*

Experiment Design: Simulation

Detailed Circuit Model Goes here



PARAMETER SWEEP

```

ParamSweep
PHD2DCSweep
SweepVar="PHD_2_DC"
Sim Instance Name(1)="PHD1A1NSweep"
Sim Instance Name(2)
Sim Instance Name(3)
Sim Instance Name(4)
Sim Instance Name(5)
Sim Instance Name(6)
Step=2
Stop=4
Step=0.1
Pk
    
```

PARAMETER SWEEP

```

ParamSweep
PHD1A1NSweep
SweepVar="PHD_1_A1N"
Sim Instance Name(1)="Tund1Sweep"
Sim Instance Name(2)
Sim Instance Name(3)
Sim Instance Name(4)
Sim Instance Name(5)
Sim Instance Name(6)
Step=0.002
Stop=0.7
Step=0.0349
Pk
    
```

PARAMETER SWEEP

```

ParamSweep
Tund1Sweep
SweepVar="PHD_Tund1"
Sim Instance Name(1)="HB1"
Sim Instance Name(2)
Sim Instance Name(3)
Sim Instance Name(4)
Sim Instance Name(5)
Sim Instance Name(6)
Step=0.6 GHz
Stop=6.6 GHz
Step=1.0 GHz
Pk
    
```

HARMONIC BALANCE

```

HarmonicBalance
HB1
Freq[1]=PHD_Tund1
Order[1]=10
StatusLevel=3
Oversample[1]=
SS_MixMode=yes
SS_Plane="SwpSSFreq"
UseAllSS_Freq=yes
SweepVar="SSPort1"
SweepPlan="SSPort1Sweep"
    
```

SWEEP PLAN

```

SweepPlan
SSPortSweep
Start1 Stop2 Step=1 Unw
UseSweepPlan
SweepPlan
Reverse=no
    
```

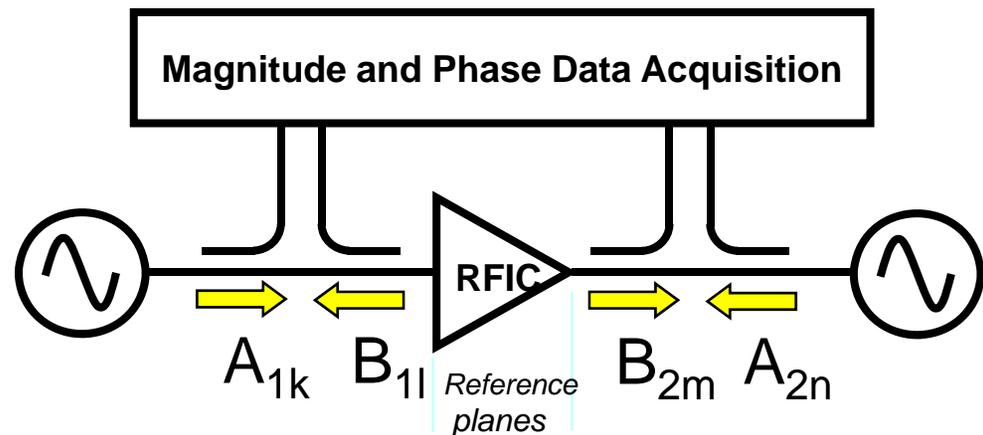
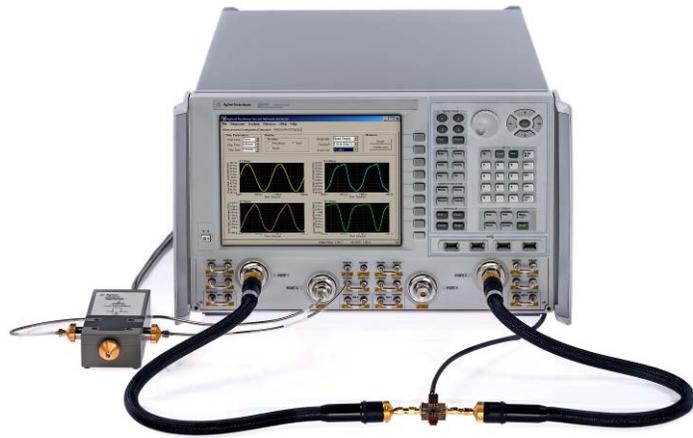
SWEEP PLAN

```

SweepPlan
SwpSSFreq
Start=0 Stop=(PHOrder-1)*PHD_Tund1 Step=PHD_Tund1 Unw
UseSweepPlan
SweepPlan
Reverse=no
    
```

Experiment Design: Measurement

Nonlinear Vector Network Analyzer [9,14] (NVNA)



New phase calibration standard

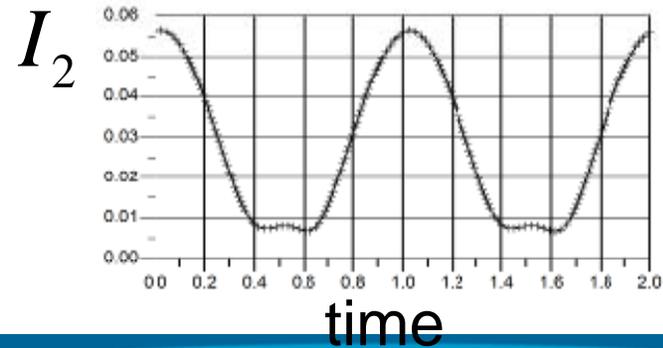
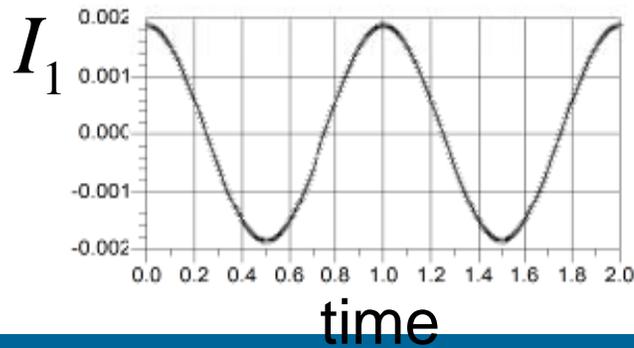
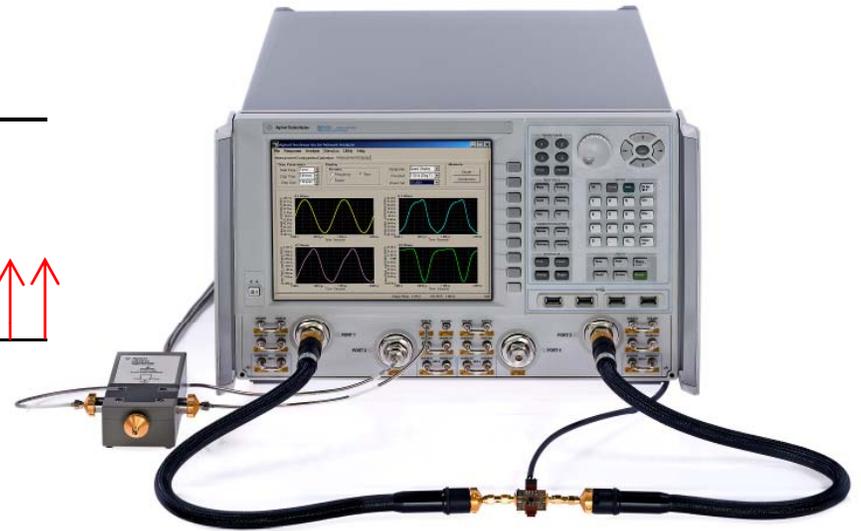
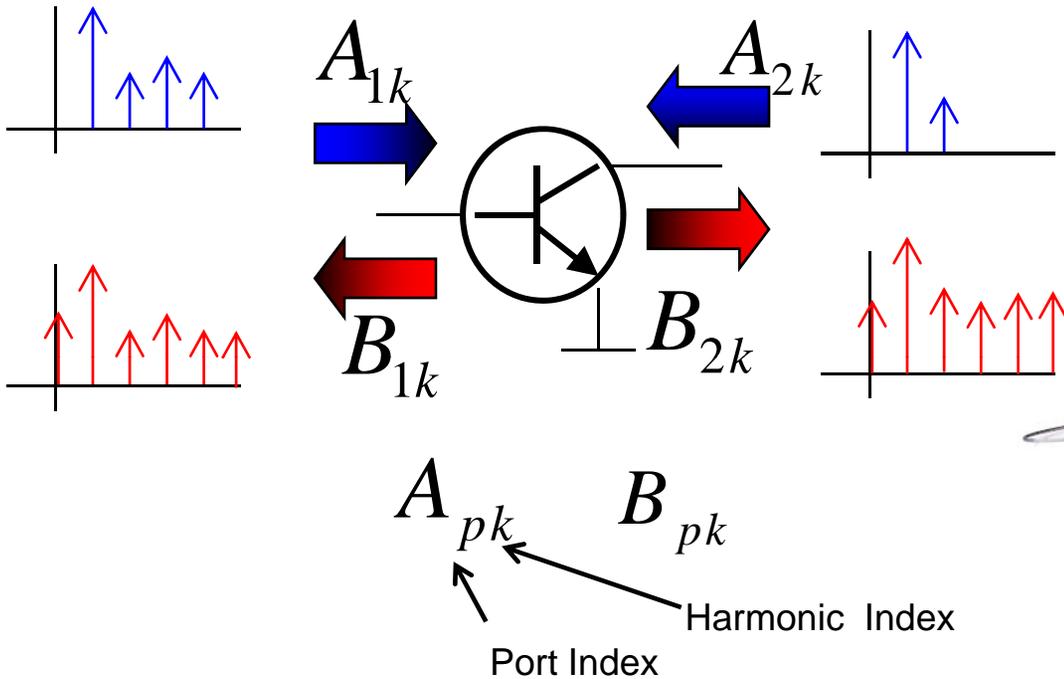
Calibrated magnitude *& phase* of harmonics/IMD

Measures under realistic large-signal conditions

Based on Standard Agilent PNA Hardware

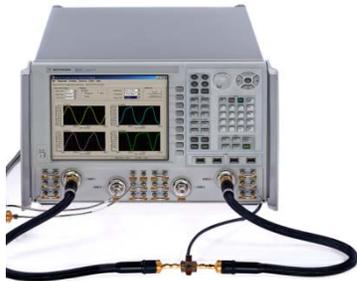
And custom reference generator

Introduction: NVNA measurements complex spectra and waveforms



Nonlinear Vector Network Analyzer (NVNA) [14]:

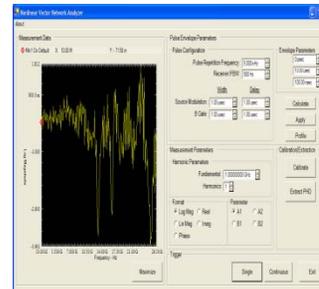
Network Analyzer



Phase Reference



Meas. Science
Algorithms & Software

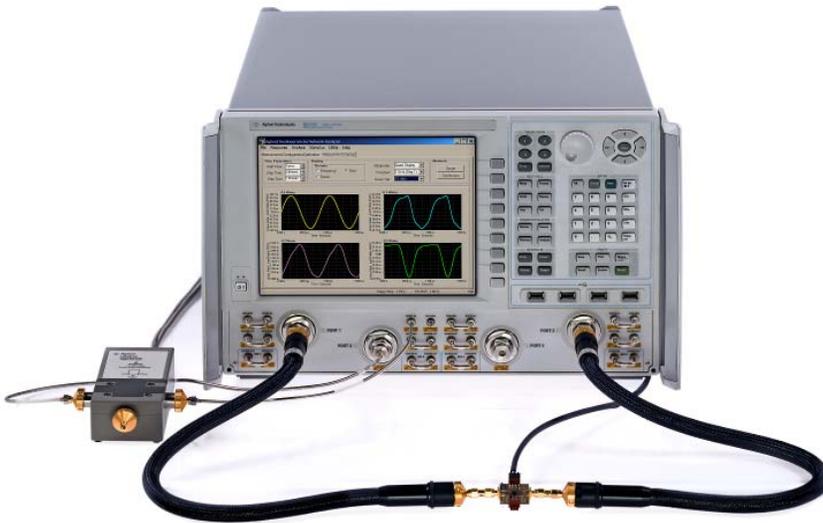


NVNA = PNA-X + Phase Reference (custom InP IC)
+ Application SW and calibration (mag and phase)
two internal sources, internal switches, and an internal broadband combiner

NVNA measures *Magnitude and Phase* of all relevant frequency components (cross-frequency coherence) necessary to measure X-parameters!

Nonlinear Vector Network Analyzer (NVNA) [14]

- Vector (amplitude/phase) corrected nonlinear measurements from 10 MHz to 50 GHz
 - Calibrated absolute amplitude and relative phase (cross-frequency relative phase) of measured spectra traceable to standards lab
 - 50 GHz of vector corrected bandwidth for time domain waveforms of voltages and currents of DUT
 - Multi-Envelope domain measurements for measurement and analysis of memory effects
 - X-parameters: Extension of Scattering parameters into the nonlinear region providing unique insight into nonlinear DUT behavior. Efficient measurements with phase control. External instrument control, pulsed, triggered measurements
 - X-parameter MDIF file read by ADS XnP component or nonlinear simulation and design.
 - X-parameter generation from detailed schematics within ADS simulator.
- **Standard VNA HW with Nonlinear features & capability**



Outline

Introduction: Behavioral Models and NVNA

Functional Block Models

- Nonlinear Time Series
- X-parameters (PHD model) in the Frequency Domain
- Mixed Time-Frequency

Summary and Conclusions

Nonlinear Time Series method of Behavioral Modeling [1,6]



Dynamical Systems & State Space

The dynamics of the nonlinear system can be assumed to be described by a system of nonlinear ODEs

$$y^{(n)}(t) = f(y^{(n-1)}, \dots, y, x, \dot{x}, \dots, x^{(m)})$$

Order of time derivative

$$\dot{\vec{u}}(t) = \vec{f}(\vec{u}(t), \vec{x}(t)) \quad \text{Vector of State Equations}$$

$$y(t) = h(\vec{u}(t), \vec{x}(t)) \quad \text{Scalar output } y(t)$$

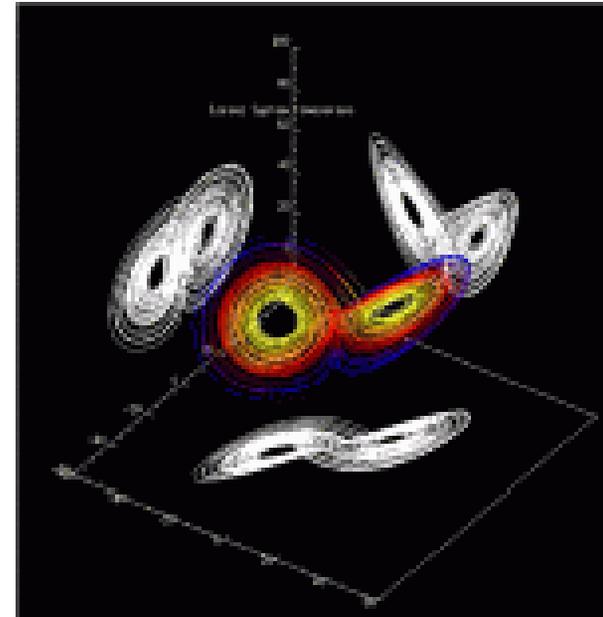
The sampled solution of the ODE, $y(t)$, is a **time-series**

The solution of the dynamical equations for state variables, $u(t)$, is a **time-parameterized** trajectory in Phase Space

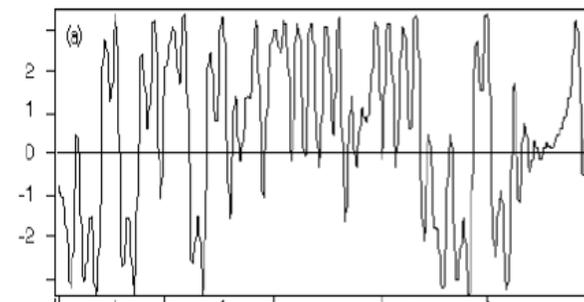
Phase Space and Time Series

Lorenz system

The multi-dimensional space spanned by the state variables is known as **phase space**



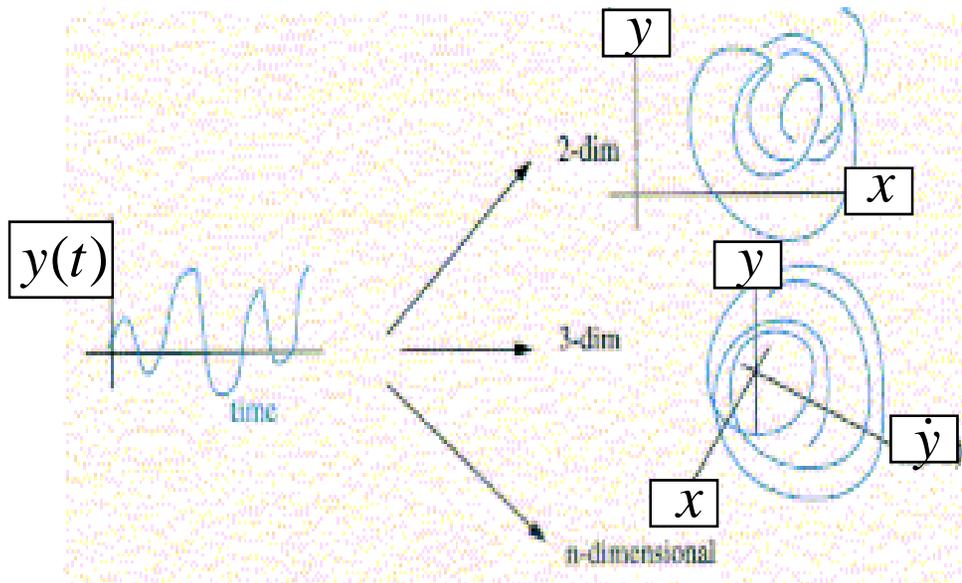
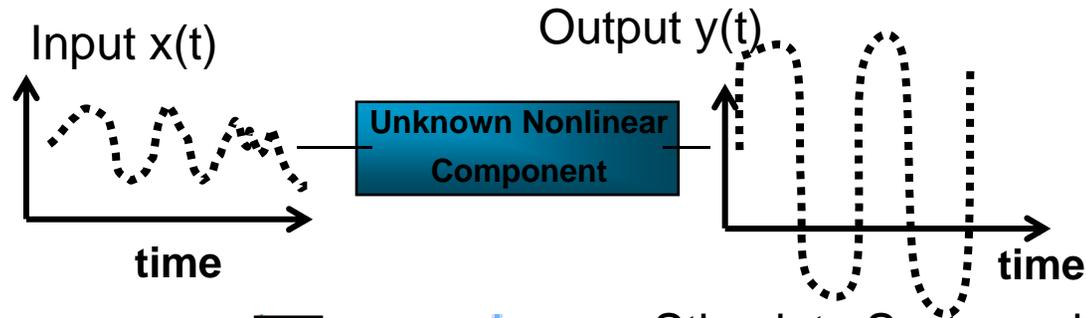
Any measurable output is a projection of this trajectory versus time:
a **Time Series**



Nonlinear Time Series (NLTS)

Phase Space Reconstruction by Embedding

NLTS Behavioral Modeling is “*inverse*” of solving known ODEs
 Start from input & output time series and *discover dynamics*



Stimulate System with drive $x(t)$

Record Time Series output $y(t)$

Embed drive $x(t)$ & response $y(t)$

Stop when trajectory single valued

This results in the *Nonlinear ODE*:

$$f(y(t), \dot{y}(t), x(t), \dots) = 0$$

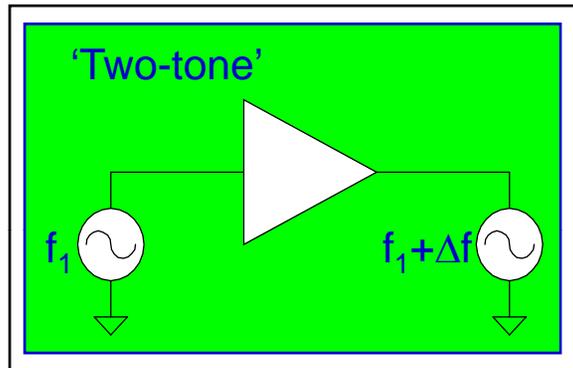
Approximate f with smooth function

Attach ODE Model to Circuit Simulator

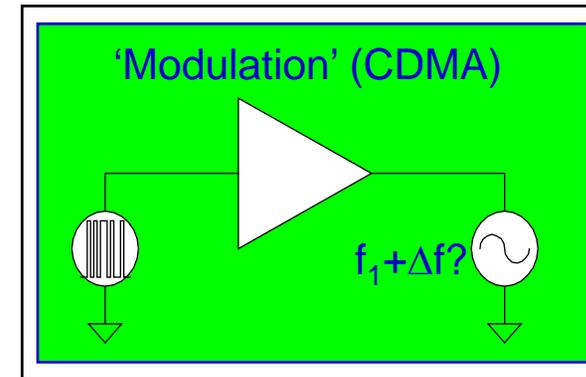
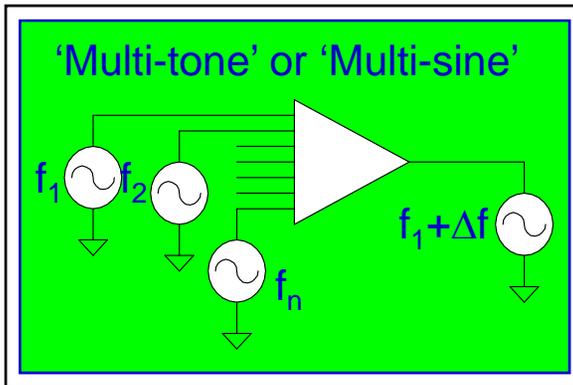
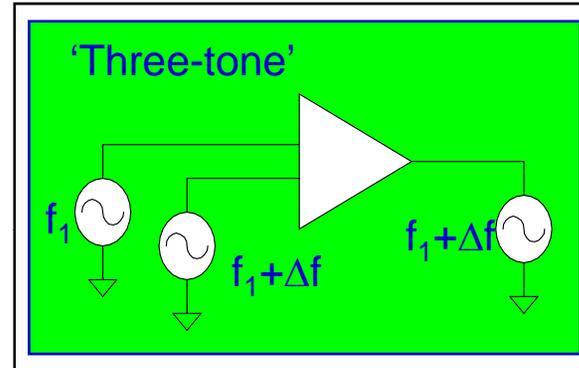
Excitation Designs

Goal: stimulate all *relevant* (observable) dynamics

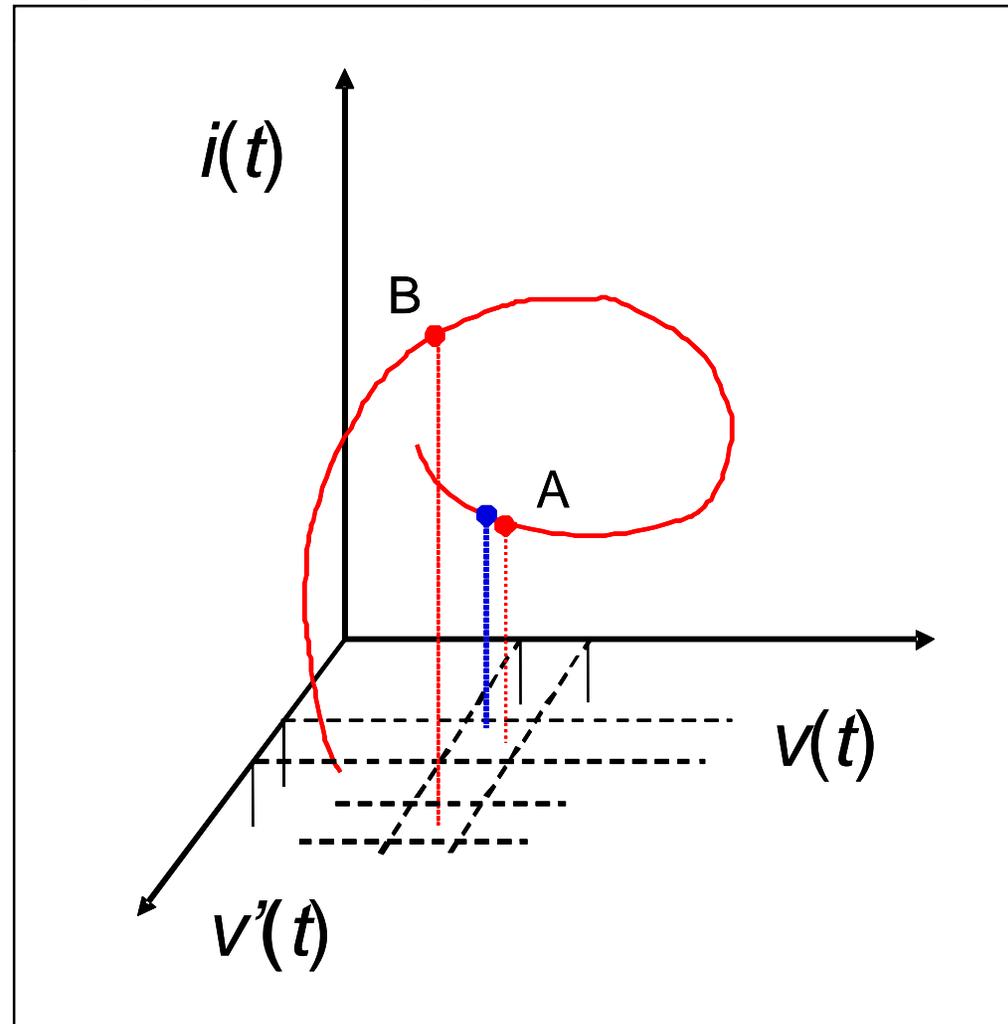
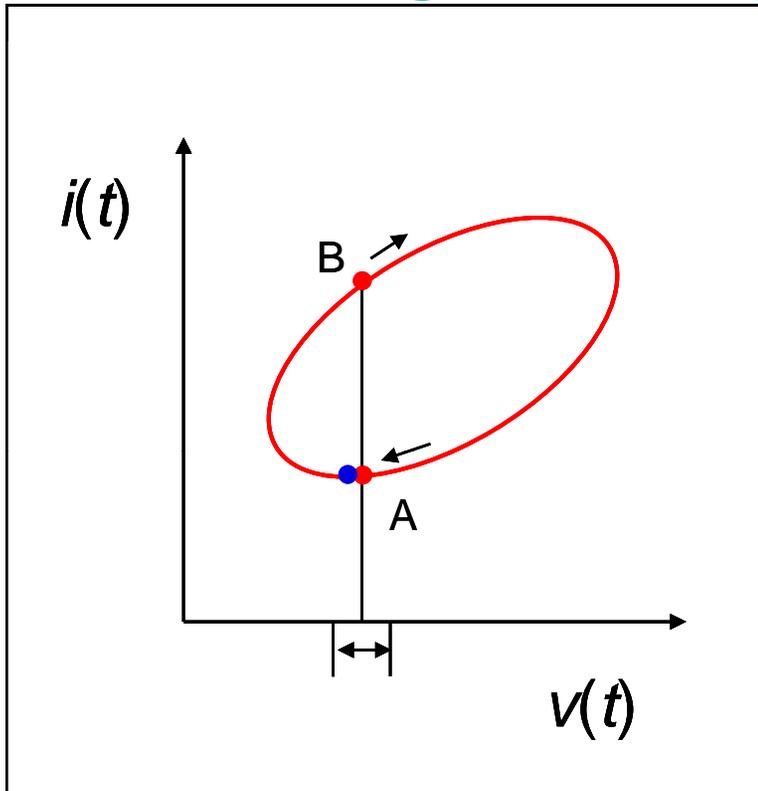
Sweep Power and Frequency to “cover phase space”



Used for
models



Embedding: Building up phase space to define ODE



$$i(t) \neq i(v(t))$$

$$i(t) = i(v(t), \dot{v}(t))$$

Model Identification: Nonlinear Time Series (NLTS)



Stimulate / Excite System
Sufficiently complex stimulus

$$x(t) \rightarrow [x(t), \dot{x}(t), \dots, x^{(m)}(t)]$$

$$y(t) \rightarrow [y(t), \dot{y}(t), \dots, y^{(n)}(t)]$$

Embed:
Create auxiliary variables
(represent waveform)

$x(t_1)$	$\dot{x}(t_1)$...	$x^{(m)}(t_1)$	$y(t_1)$	$\dot{y}(t_1)$...	$y^{(n)}(t_1)$
$x(t_2)$	$\dot{x}(t_2)$...	$x^{(m)}(t_2)$	$y(t_2)$	$\dot{y}(t_2)$...	$y^{(n)}(t_2)$
.
$x(t_p)$	$\dot{x}(t_p)$...	$x^{(m)}(t_p)$	$y(t_p)$	$\dot{y}(t_p)$...	$y^{(n)}(t_p)$

Sample data:

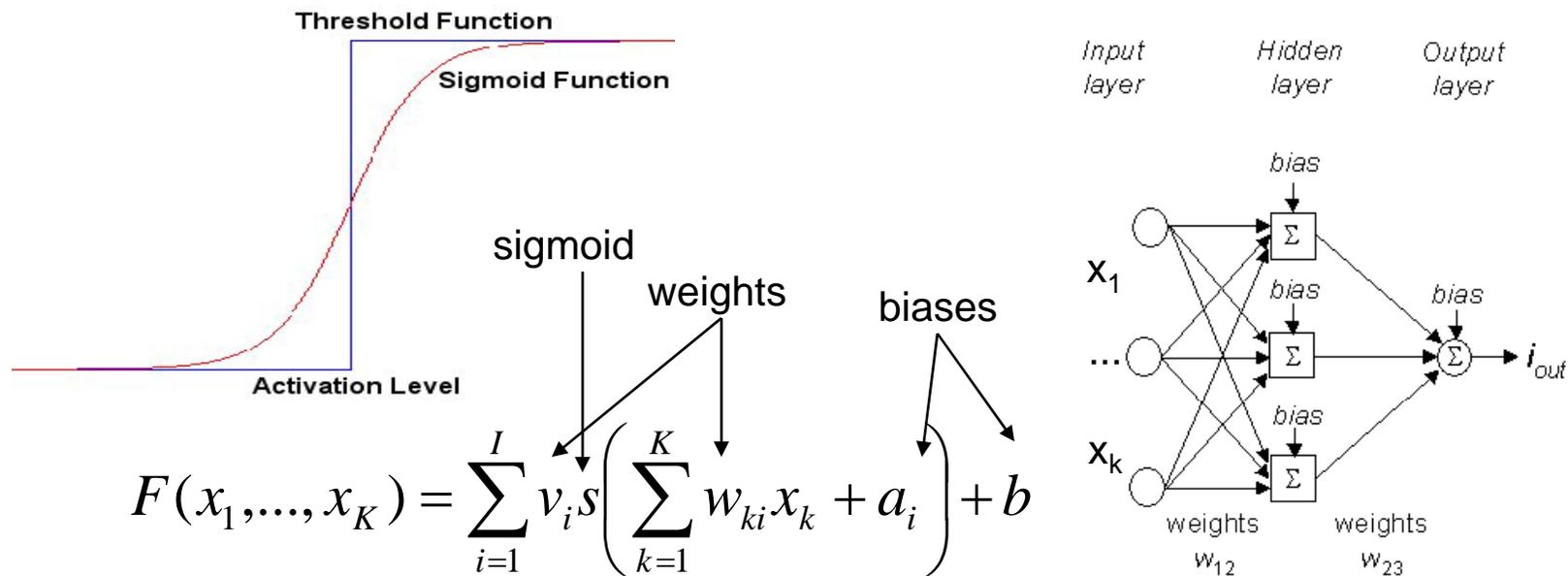
at high frequency
(or envelope;
hard if multiple timescales)

$$y^{(n)} = f(y^{(n-1)}, \dots, y, x, \dot{x}, \dots, x^{(m)})$$

Fit:
Nonlinear function f

Function approximation Artificial Neural Networks

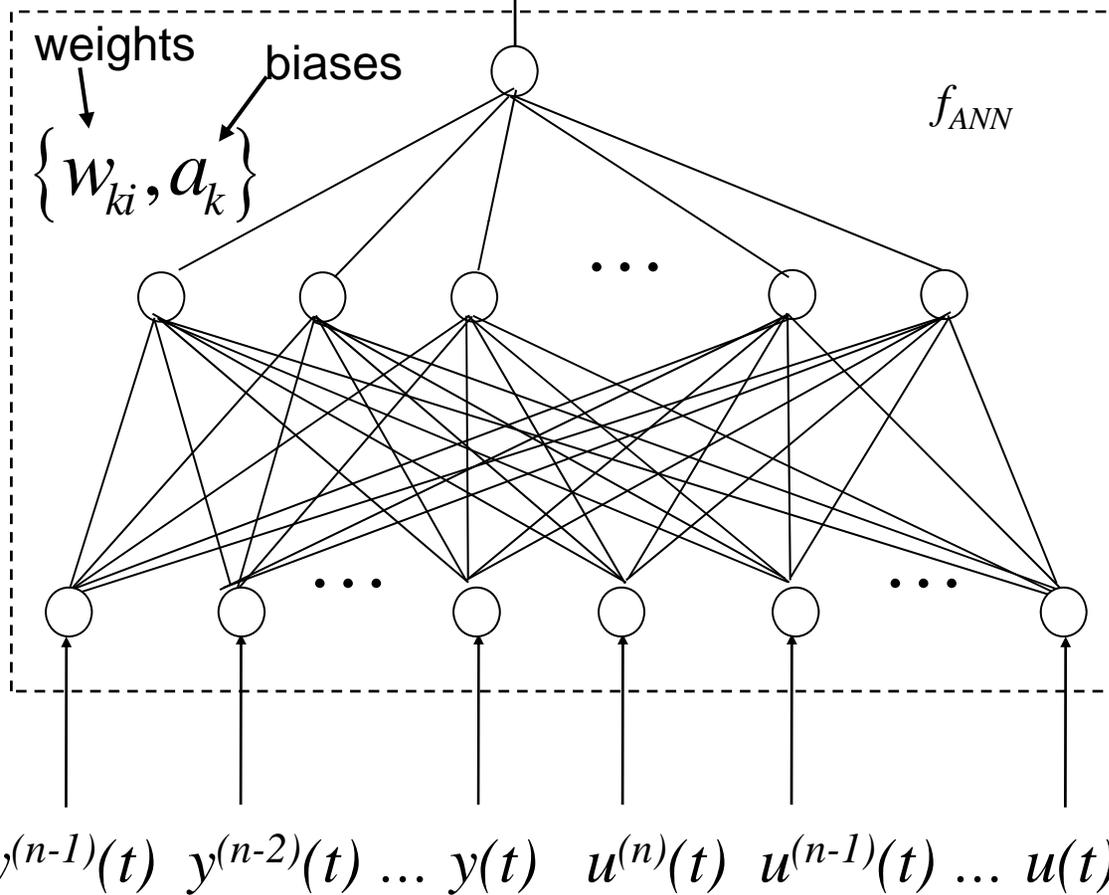
An ANN is a parallel processor made up of simple, interconnected processing units, called *neurons*, with weighted connections.



- Universal Approximation Theorem: Fit “any” nonlinear function of any # of variables
- Infinitely differentiable: *better for distortion than naïve splines or low-order polynomials.*
- Easy to train (fit) using standard third-party tools (MATLAB)
- Easy to train on scattered data

Function approximation: Artificial Neural Networks

$$y^{(n)}(t) = f_{ANN}(y^{(n-1)}(t), y^{(n-2)}(t), \dots, y(t), u^{(n)}(t), u^{(n-1)}(t), \dots, u(t))$$



“Dynamic Neural Network”

$\{w_{ki}, a_k\}$ Obtained by *Training*

Can also define f by polynomials, radial basis functions, lookup tables etc.

Model Implementation: ODE in circuit simulator

(after Zhang and Xu in [6])

$$y^{(n)} = f(y^{(n-1)}, \dots, y, x, \dot{x}, \dots, x^{(m)})$$

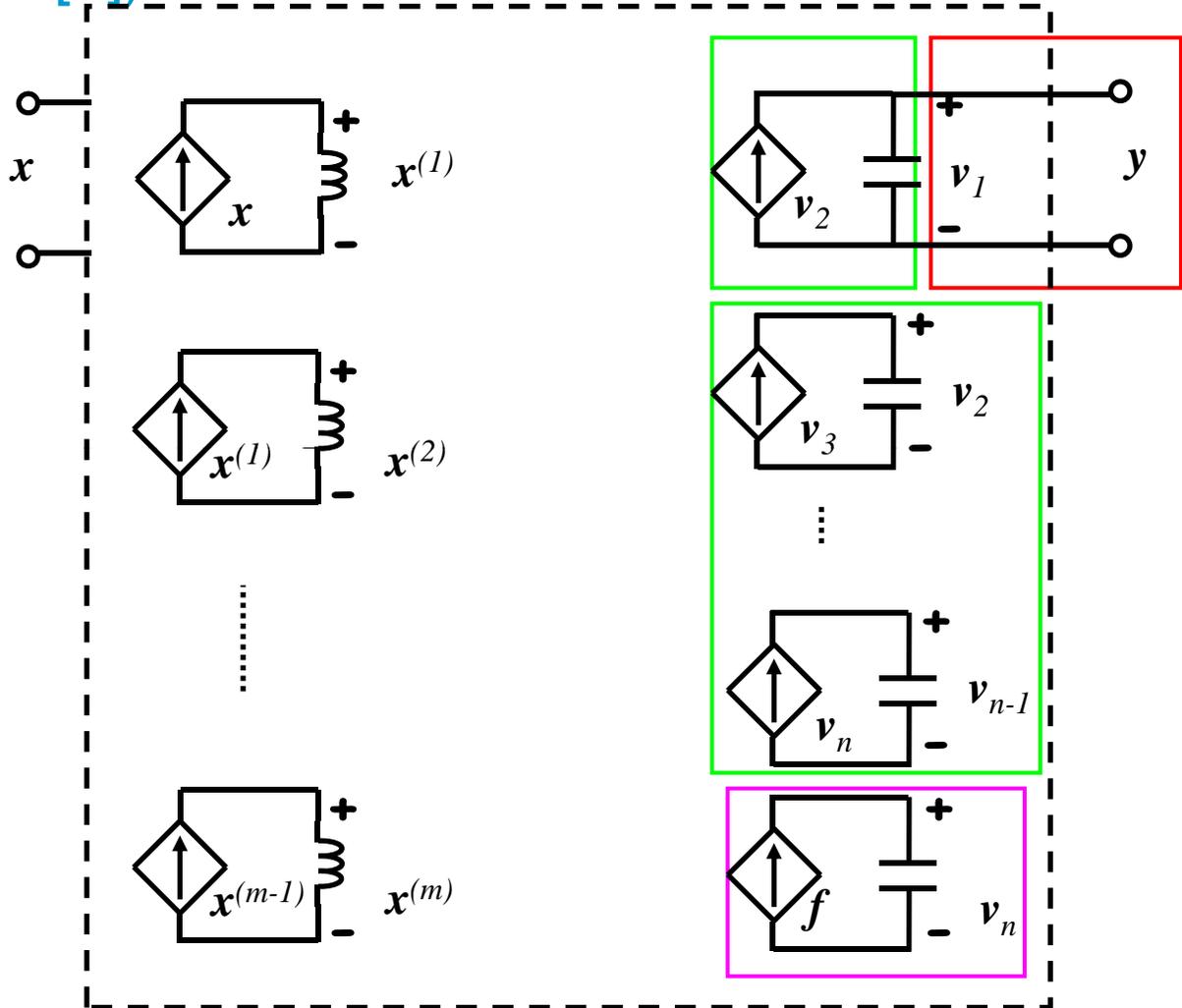
$$v_1 = y$$

$$\dot{v}_1 = v_2$$

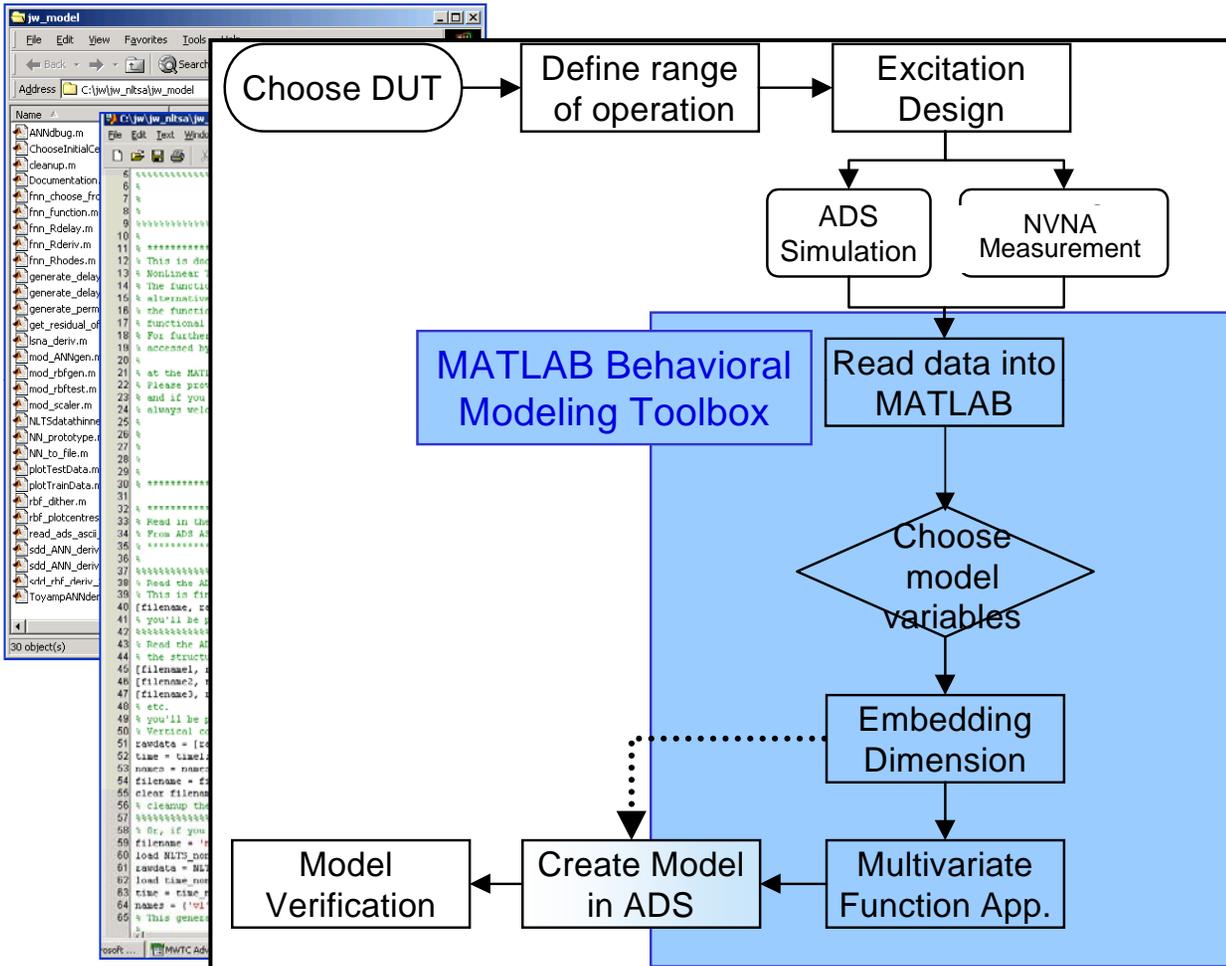
⋮

$$\dot{v}_{n-1} = v_n$$

$$\dot{v}_n = f(v_{n-1}, v_{n-2}, \dots, v, x, \dot{x}, \dots, x^{(m)})$$



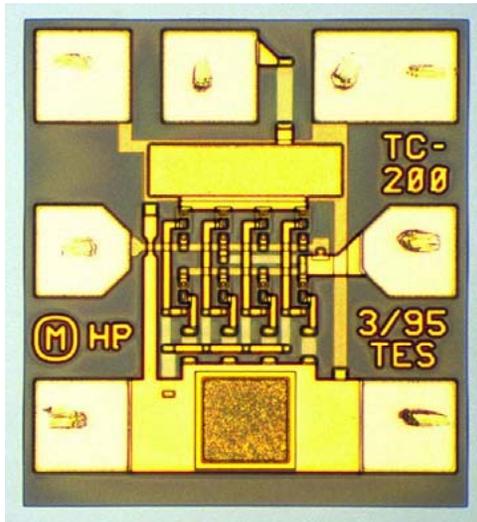
NL TSA modeling flow



- *MATLAB* Toolbox, plus 3rd-party software
- ‘*NLTSfile*’ structure
- *ADS/NVNA-MATLAB* interfaces
- *ADS* templates for
 - simulation
 - data display
 - model verification
- Model as *SDD* in *ADS*

Example: GaAs HBT MMIC

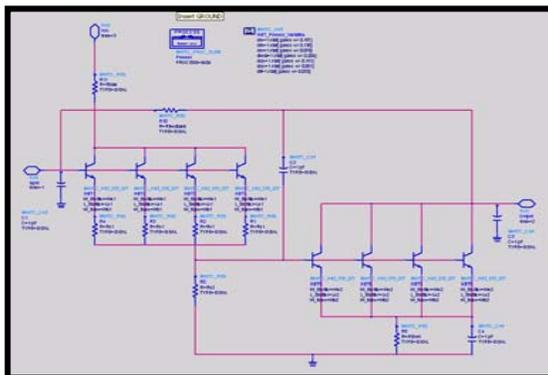
Actual Circuit



**DC-20 GHz GaAs HBT
(Agilent HMMC 5200 Amp)**

Series-Shunt Amplifier

Gain: 9.5 dB @ 1.5GHz

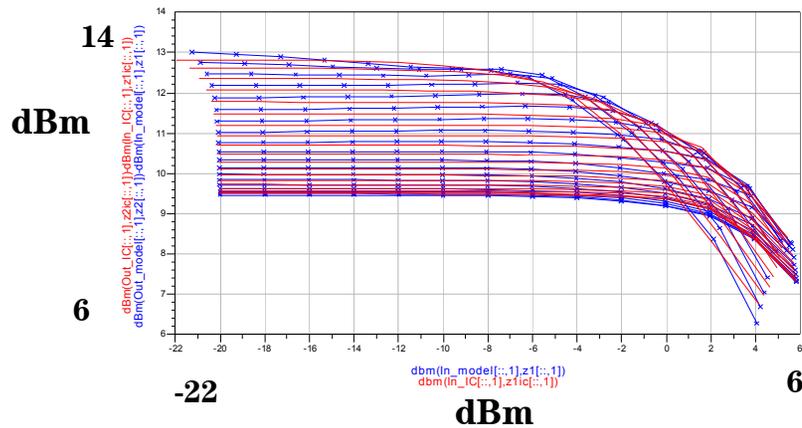


Detailed ckt model

Results: NLTS Accuracy and Speed [1,6]

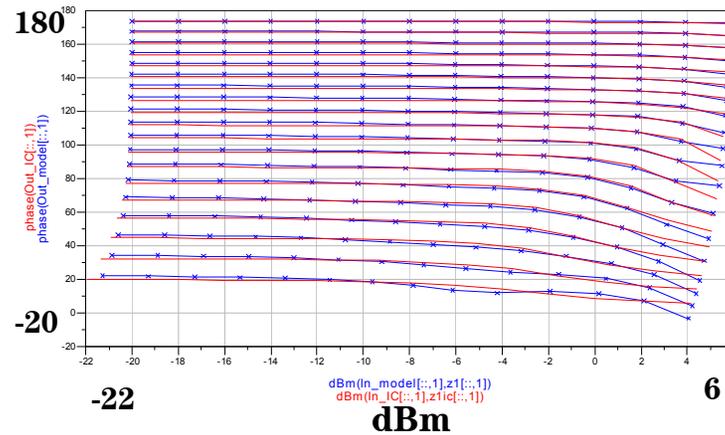
NLTS Behavioral model

Fundamental Gain



Circuit model data

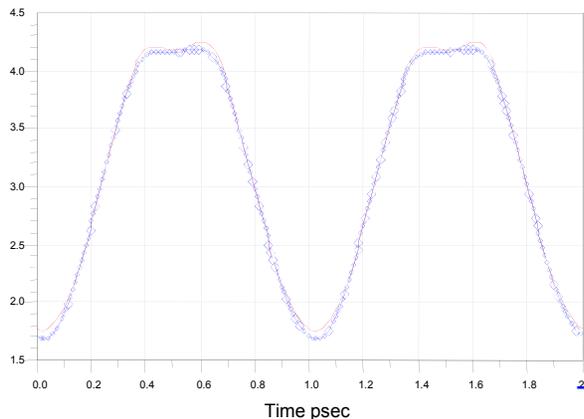
Fundamental Phase



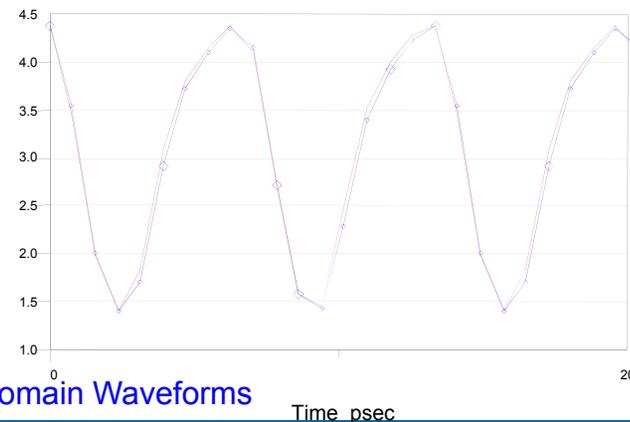
1 - 19 GHz

$$I_i(t) = f_i(\dot{I}_i, V_1(t), V_2(t), \dot{V}_1(t), \dot{V}_2(t), V_1^{(2)}(t), V_2^{(2)}(t))$$

19 neurons



Time Domain Waveforms



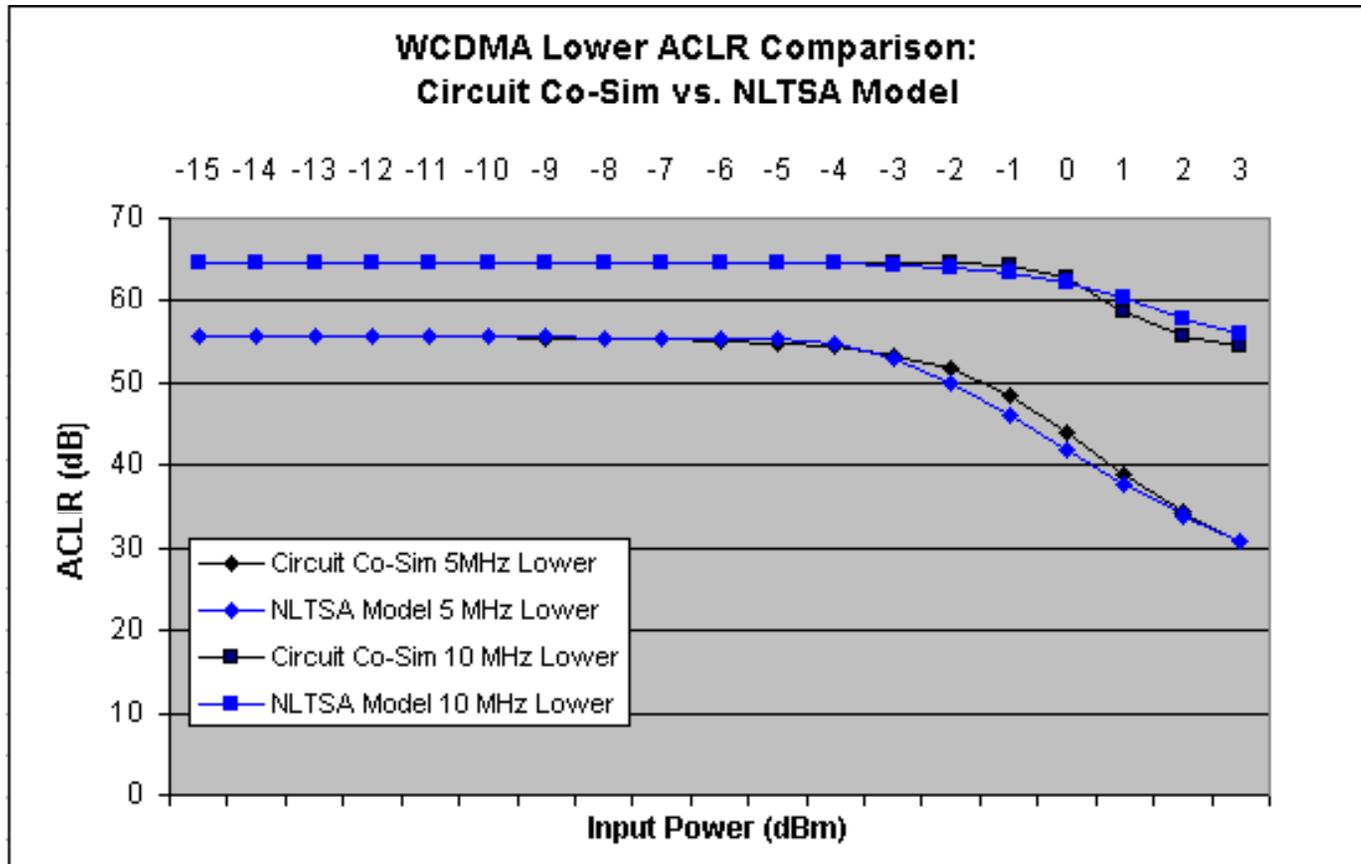
Time_psec

229.68 seconds

11315.67 seconds

Circuit Co-Simulation vs. NLTSA Model

Results 3GPP WCDMA (lower) ACLR



3GHz WCDMA
Model generated from only sinusoidal signals

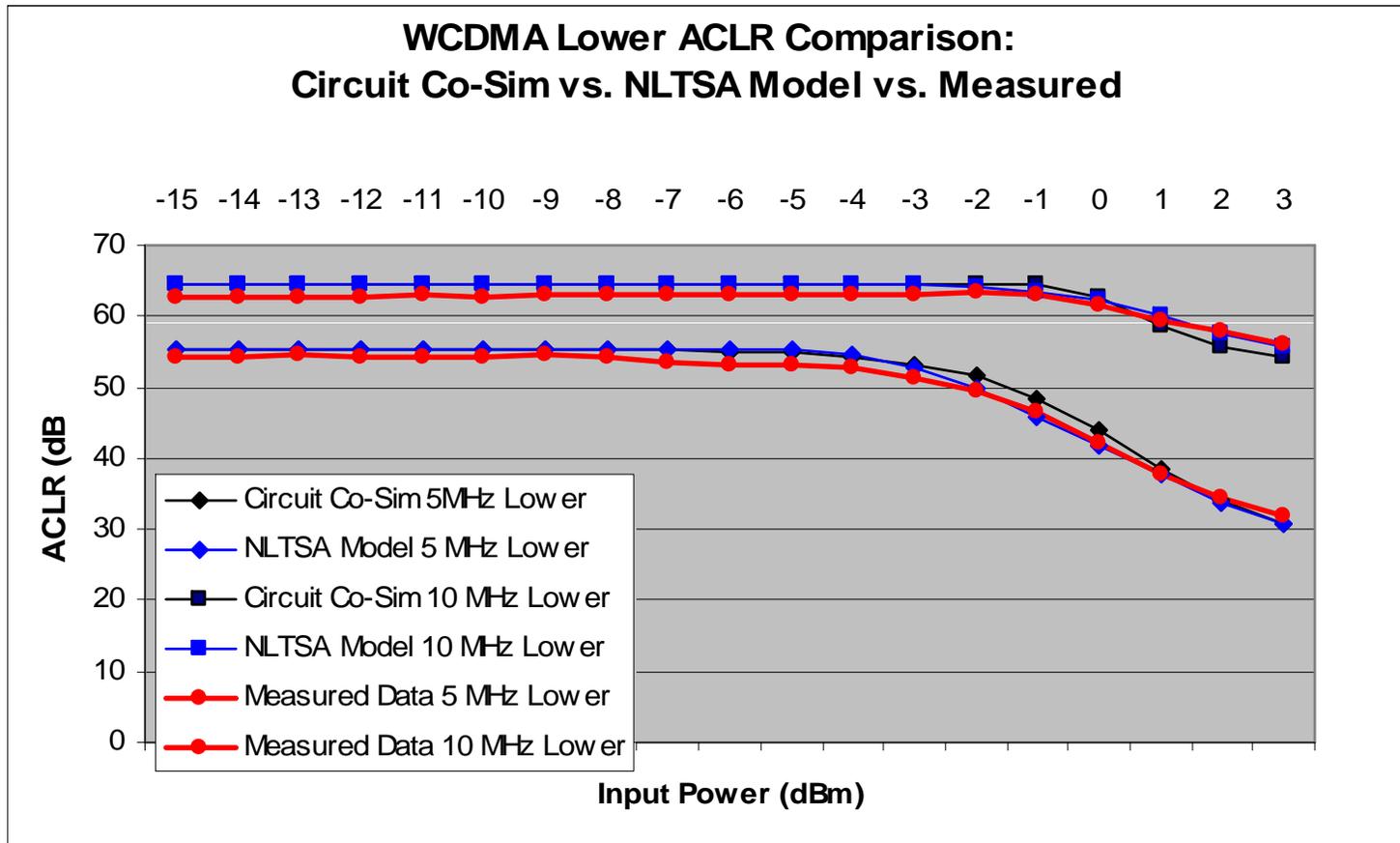
294 sec/pt NLTS

1532 sec/pt Ckt.

40 neuron model

Courtesy Greg Jue

Circuit Co-Simulation vs. NLTSA Behavioral Model Results vs. Measured 3GPP WCDMA (lower) ACLR



3GHz simulated
2.4GHz meas

Model is also *cascadable*

Model works in TA, HB, Envelope

Outline

Introduction: Behavioral Models and NVNA

Functional Block Models

- Nonlinear Time Series
- X-parameters (PHD Model) in the Frequency Domain
- Mixed Time-Frequency Methods

Summary and Conclusions

X-parameters (PHD model): a *nonlinear* paradigm

“Is there an analogue with linear S-parameters to help with the nonlinear problem?”



Frequency Domain description is natural for high-frequency, distributed systems

Natural for Harmonic Balance Algorithms and NVNA data

Arbitrarily Nonlinear, Not limited to Volterra Theory

X-Parameters: The Nonlinear Paradigm

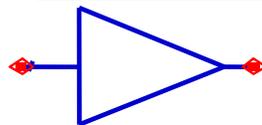
X-parameters are the mathematically correct superset of S-parameters, applicable to both large-signal and small-signal conditions, for linear and nonlinear components. *The math exists!*

We can measure, model, & simulate with X-parameters
Each part of the puzzle has been created
The pieces now fit together seamlessly

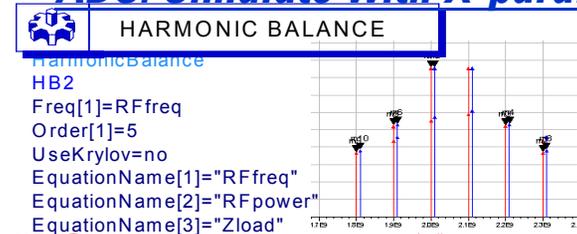
NVNA: Measure X-params



X-parameter block



ADS: Simulate with X-params



Interoperable Nonlinear Measurement, Modeling & Simulation with X-params

“X-parameters have the potential to do for characterization, modeling, and design of nonlinear components and systems what linear S-parameters do for linear components & systems”

X-Parameters: Why They are Important:

Predict performance of cascaded NL components

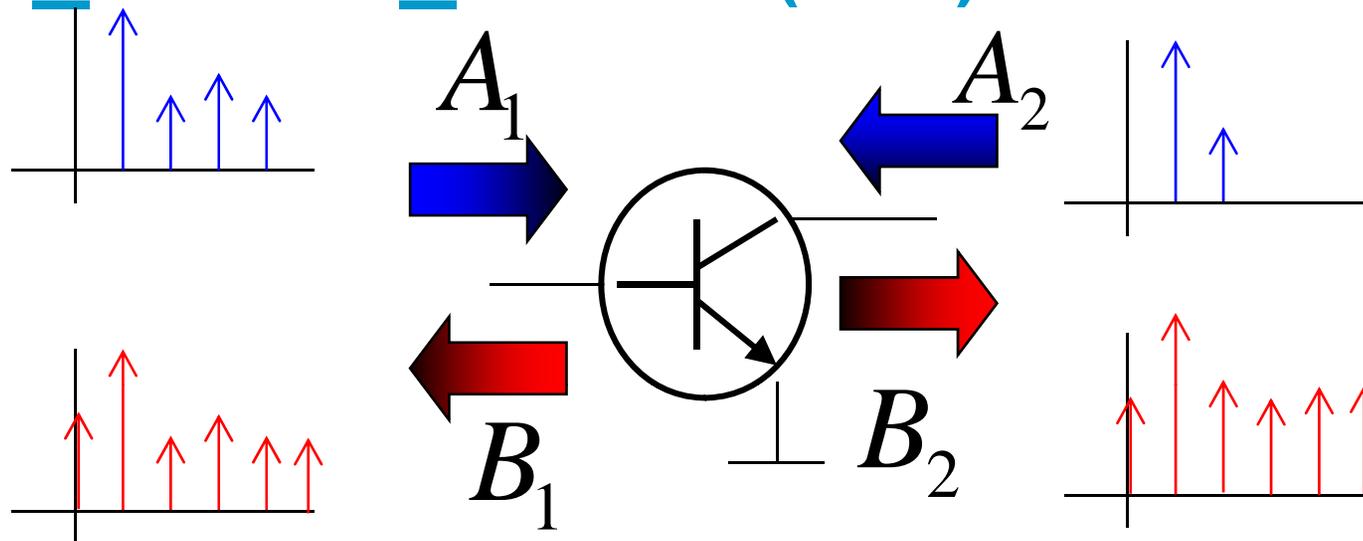
Cascaded Nonlinear Amplifiers:

X-parameters enable nonlinear simulation from measured data in the presence of mismatch



- Unambiguously identifiable from a simple set of measurements
- Extremely accurate for high-frequency, distributed nonlinear systems
- Fully nonlinear vector quantities (Magnitude *and* phase of all harmonics)
- Cascadable (correct behavior in mismatched environment)

X-parameters come from the Poly-Harmonic Distortion (PHD) Framework [3-6,12]



$$B_{1k} = F_{1k} (DC, A_{11}, A_{12}, \dots, A_{21}, A_{22}, \dots)$$

$$B_{2k} = F_{2k} (DC, A_{11}, A_{12}, \dots, A_{21}, A_{22}, \dots)$$

Port Index \nearrow \nwarrow Harmonic (or carrier) Index

Spectral map of complex *large* input phasors to *large* complex output phasors

Black-Box description holds for transistors, amplifiers, RF systems, etc.

X-parameters: Simplest Case - driven with single large tone at port 1 [1] (derivation in lecture 2)

$$B_{e,f} = F_{e,f} (DC, A_{11}, A_{12}, \dots, A_{21}, A_{22}, \dots)$$

Concept: simplify general nonlinear spectral mapping by spectral linearization

$$B_{e,f} = X_{ef}^{(F)}(|A_{11}|)P^f + \sum_{g,h} X_{ef,gh}^{(S)}(|A_{11}|)P^{f-h} \cdot A_{gh} + \sum_{g,h} X_{ef,gh}^{(T)}(|A_{11}|)P^{f+h} \cdot A_{gh}^*$$

Perfectly matched response

Mismatch terms:
linear in A_{gh}

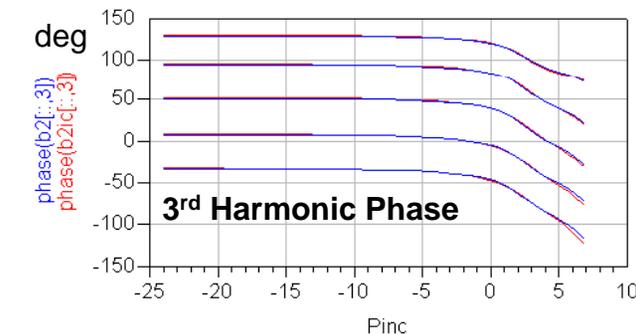
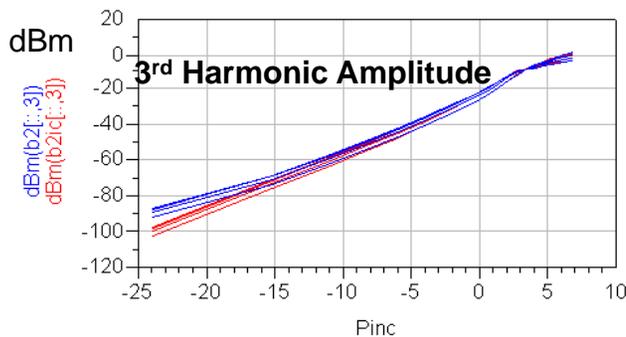
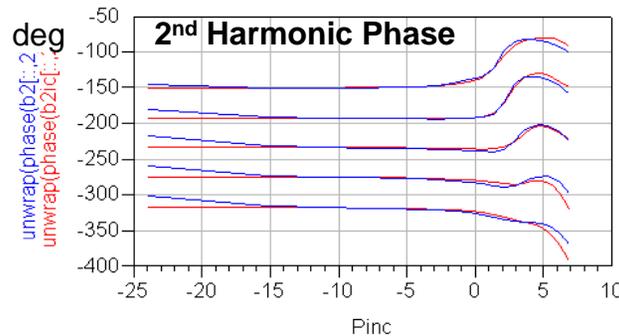
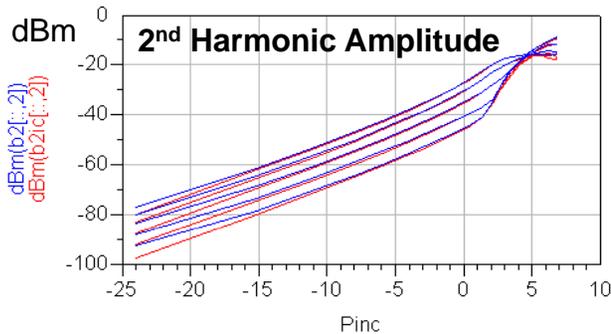
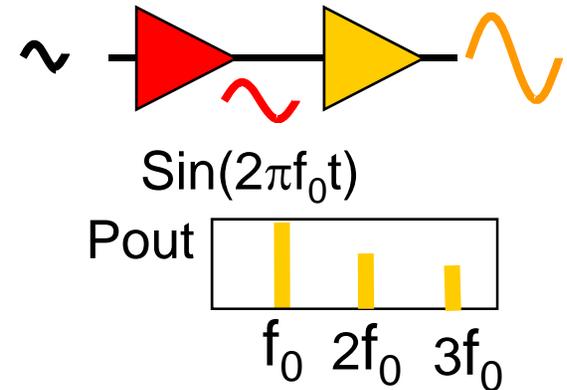
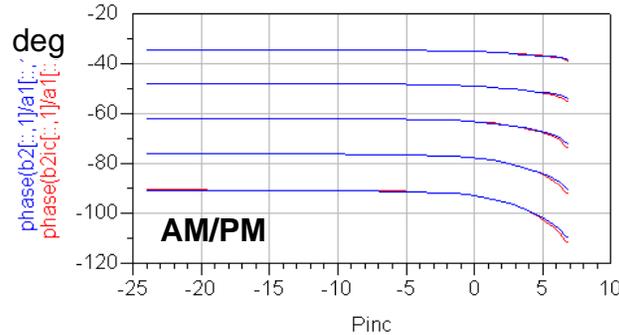
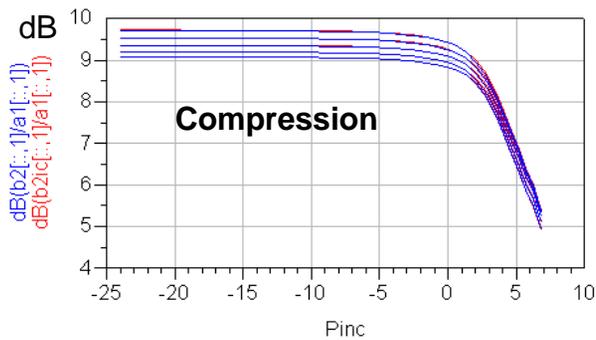
Mismatch terms:
linear in A_{gh}^*

Not both g and h = 1 in sums $P = e^{j\phi(A_{11})}$

Phase terms come from time-invariance:

“Output of delayed input is just the delayed output”

X-parameter Results: Cascadability of Nonlinear Blocks



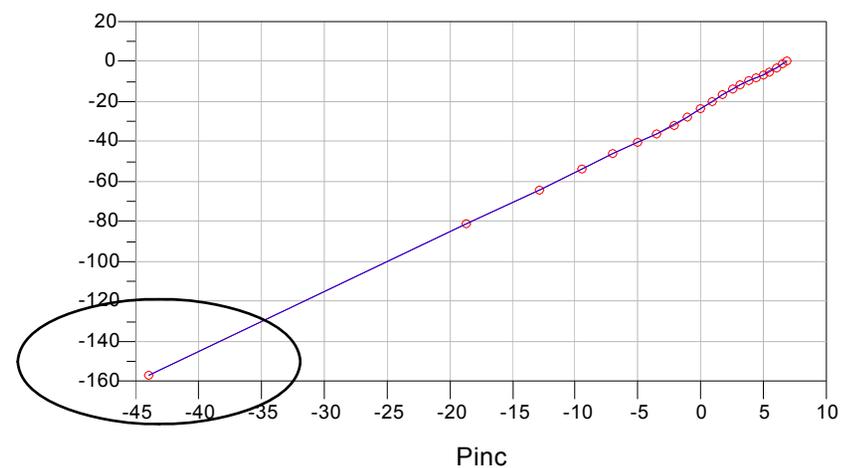
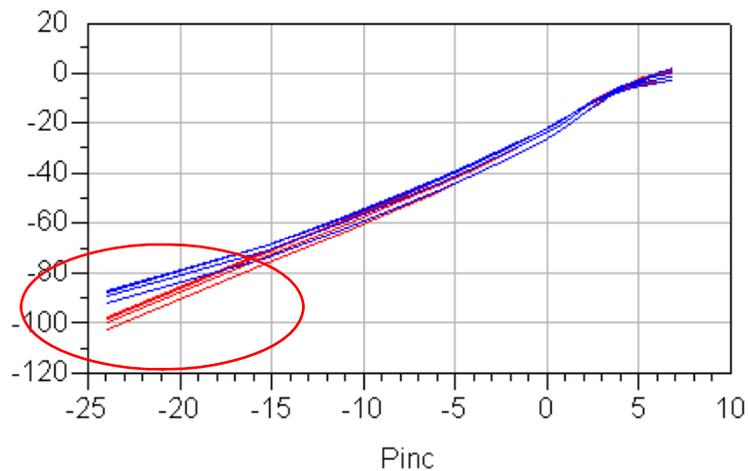
Cascaded PHD models
Cascaded Ckt. Models

0.6GHz – 6.0GHz

Does for distortion of *nonlinear components* what S-parameters do for linear components

Improved Asymptotic Behavior

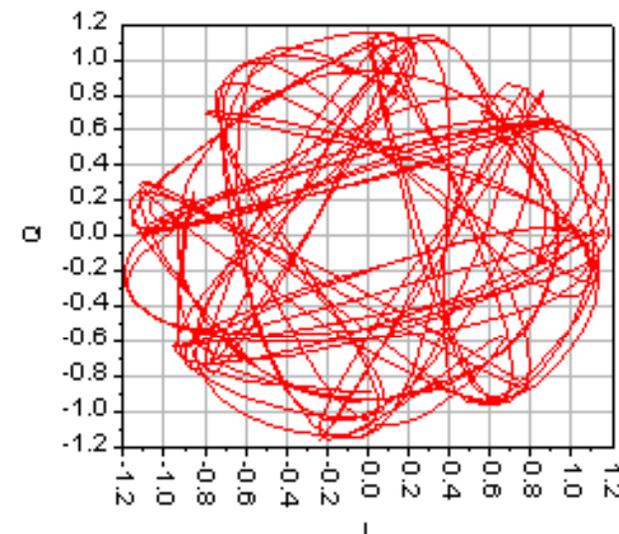
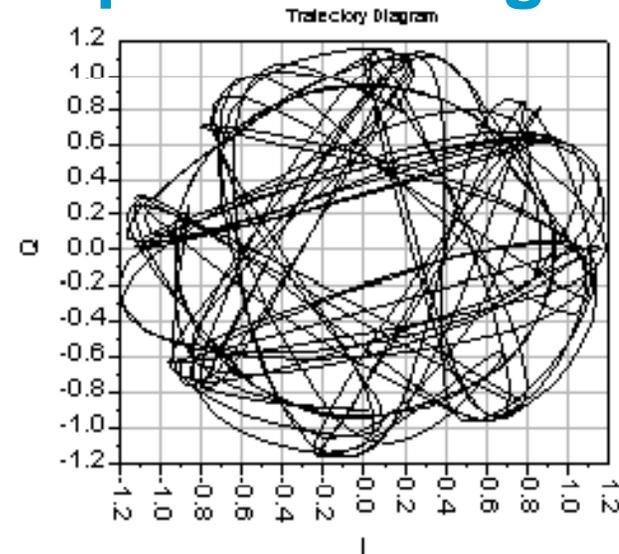
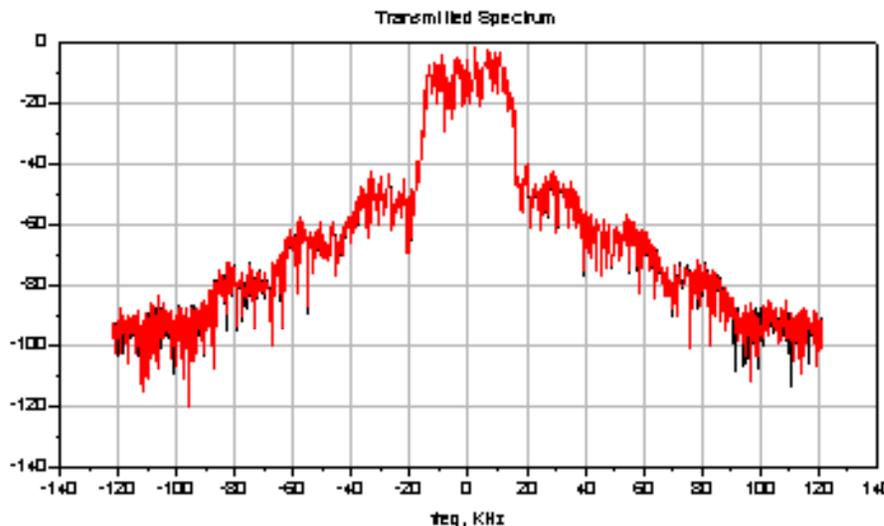
Volterra Theory Constraints Added for Improved asymptotic behavior at low power



X-parameters: HMMC 5200 Response to Digital Modulation

Circuit Model

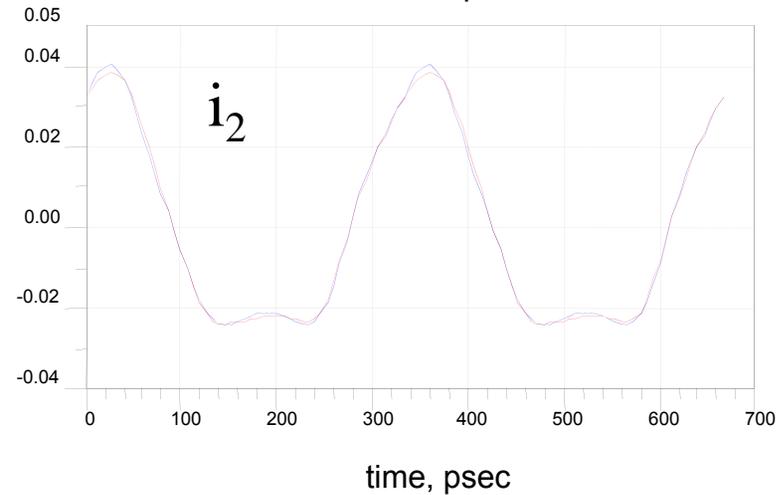
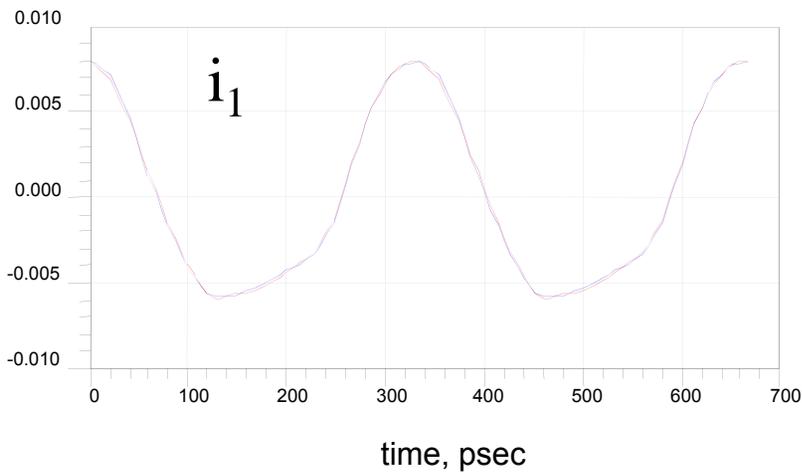
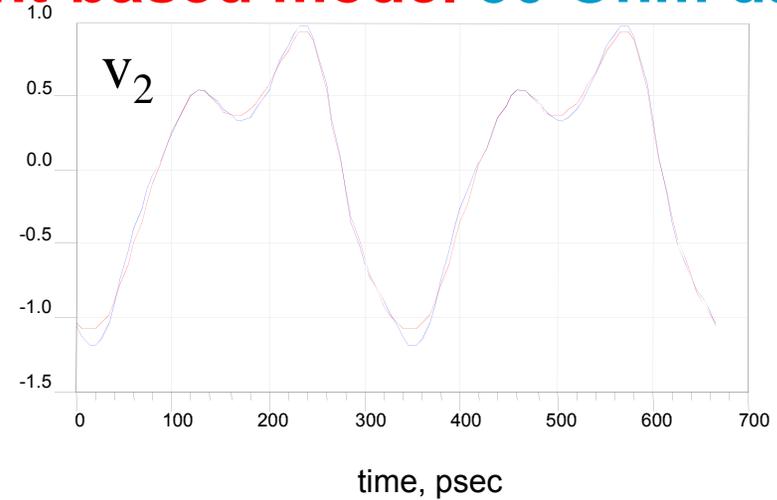
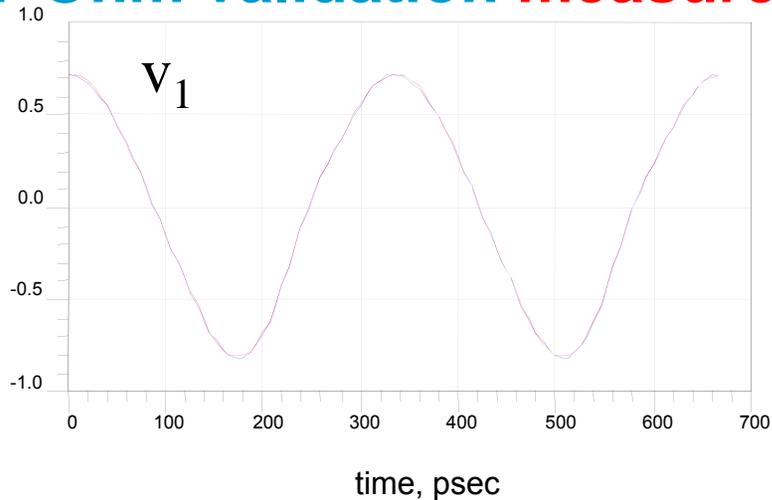
X-parameters
generated
from ckt model



Excellent Results from Simple Excitations

X-parameter Results: Transportability

27 Ohm validation **measurement-based model** 50 Ohm data



Measurement-Based X-parameter Model

Independent NVNA Data

Rough Comparison of Methods and Applicability

NLTSA

Works in TA, HB, Envelope

Excellent for strongly nonlinear, but lumped (low order ODE) systems

Training non-algorithmic

Experiment design not fully solved

Not as robust for convergence

Scales well with complexity

Great gains in simulation speed

X-Parameters

Frequency Domain natural for highly linear, distributed, broad-band ckts

Experiment Design completely solved

Highly automated Model Identification

Works in HB & Envelope

Very robust for convergence

Always accurate if sampled densely

Complexity increases rapidly for multiple tones

Outline

Introduction: Behavioral Models and NVNA

Functional Block Models

- Nonlinear Time Series
- X-parameters (PHD Model) in the Frequency Domain
- Mixed Time-Frequency Methods

Summary and Conclusions

Envelope Domain for Long-Term Memory [7,8]

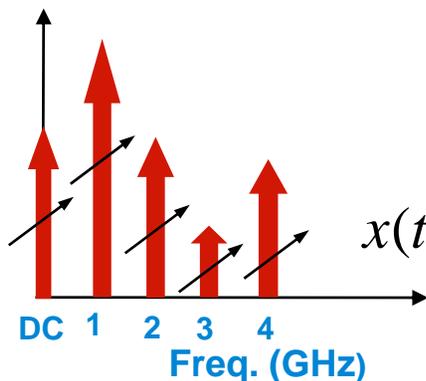
Applies to systems under large-signal modulated drives

Time-varying spectra for all inputs, outputs, & state variables

Perfectly suited for Circuit Envelope Analysis

Well-matched for data from Nonlinear Vector Network Analyzer

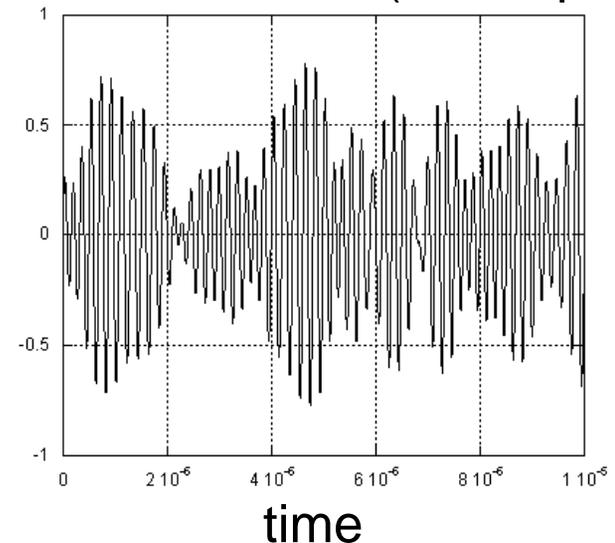
Time-varying spectrum



$$x(t) = \text{Re} \left(\sum_{h=0}^H X_h(t) e^{j 2\pi h f_0 t} \right)$$

$B_2(t)$

Time Domain (envelope)



$X_h(t)$ set of *complex* (amplitude and phase) *waveforms* at each harmonic index h
Modeling problem: *map input envelopes to output envelopes*

Envelope Domain for Long-Term Memory [7,8]

Merge Frequency and Time Domains

Spectral mapping $B_{pk} = X_{pk}^{(F)}(A_{11}, A_{12}, \dots, A_{21}, A_{22}, \dots)$
→ a differential equation *in the envelope domain*

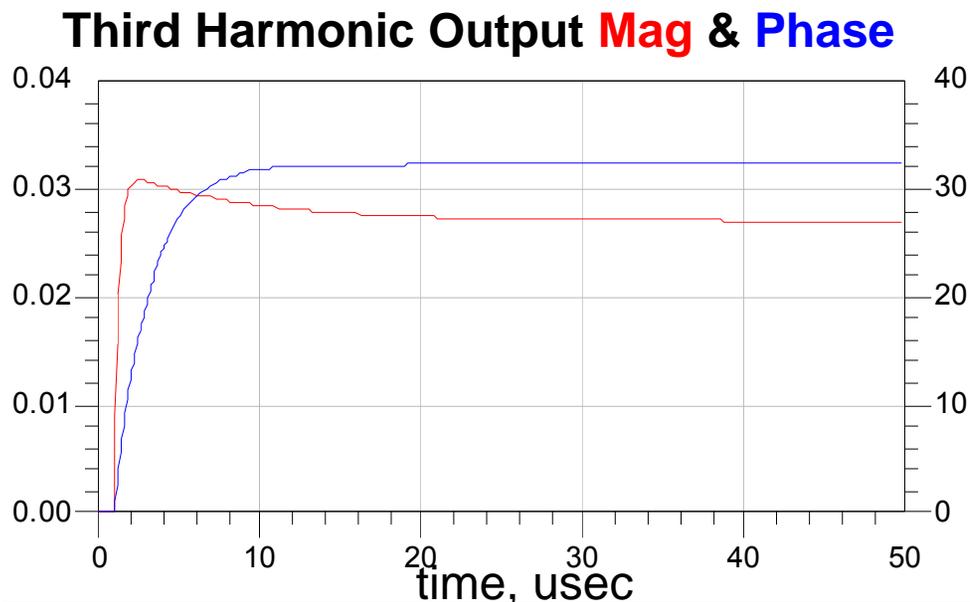
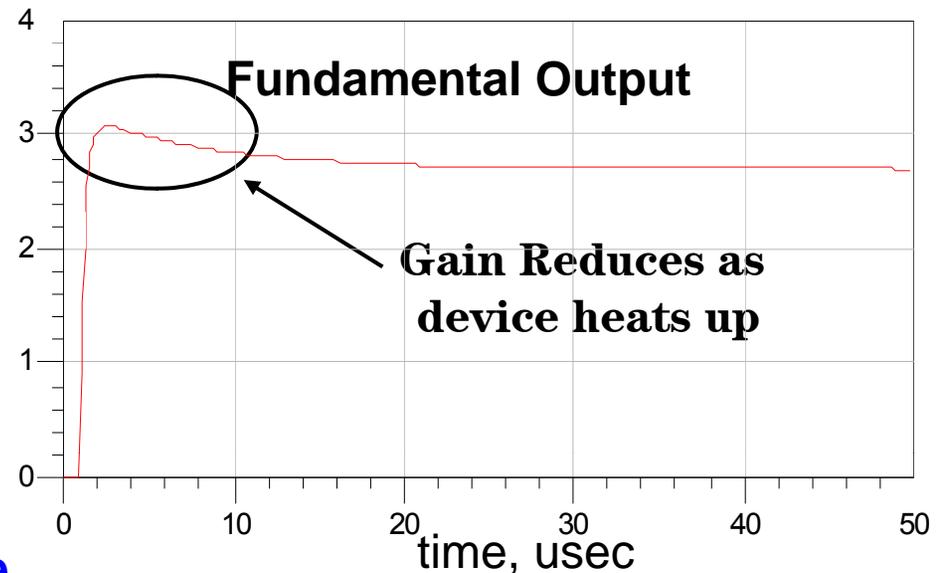
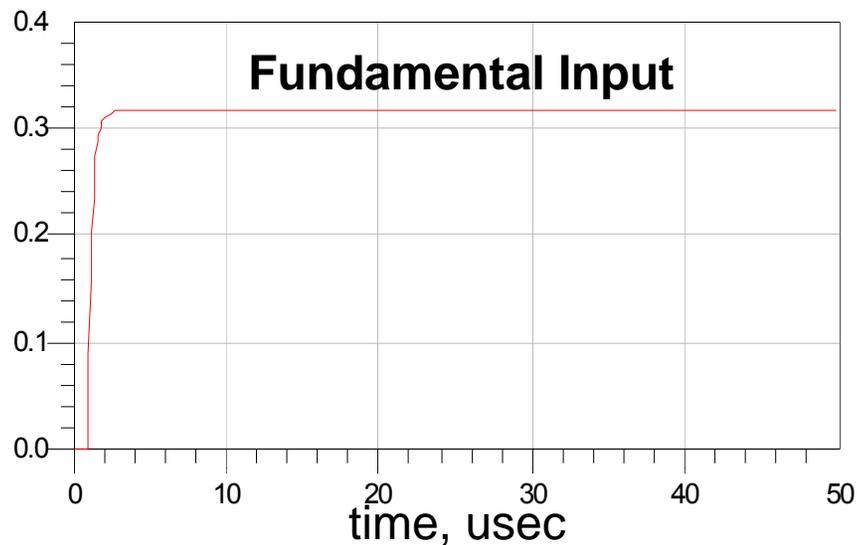
$$\hat{B}_k = f_k(\hat{B}_k^{(1)}(t), \dots, \hat{B}_k^{(n)}(t), \hat{A}_l(t), \hat{A}_l^{(1)}(t), \dots, \hat{A}_k(t), \dots, \hat{A}_k^{(m)}(t))$$

↑ Order of time derivative
Envelope or carrier index

Example:

$$\hat{B}_{21}(t) = f_{21}(\hat{B}_{20}(t), \hat{A}_{11}(t))$$
$$\frac{d\hat{B}_{20}(t)}{dt} = g(\langle |\hat{A}_{11}(t)|^2 \rangle, \hat{B}_{21}(t))$$

Envelope Model: Amplifier with Self-Heating [8]



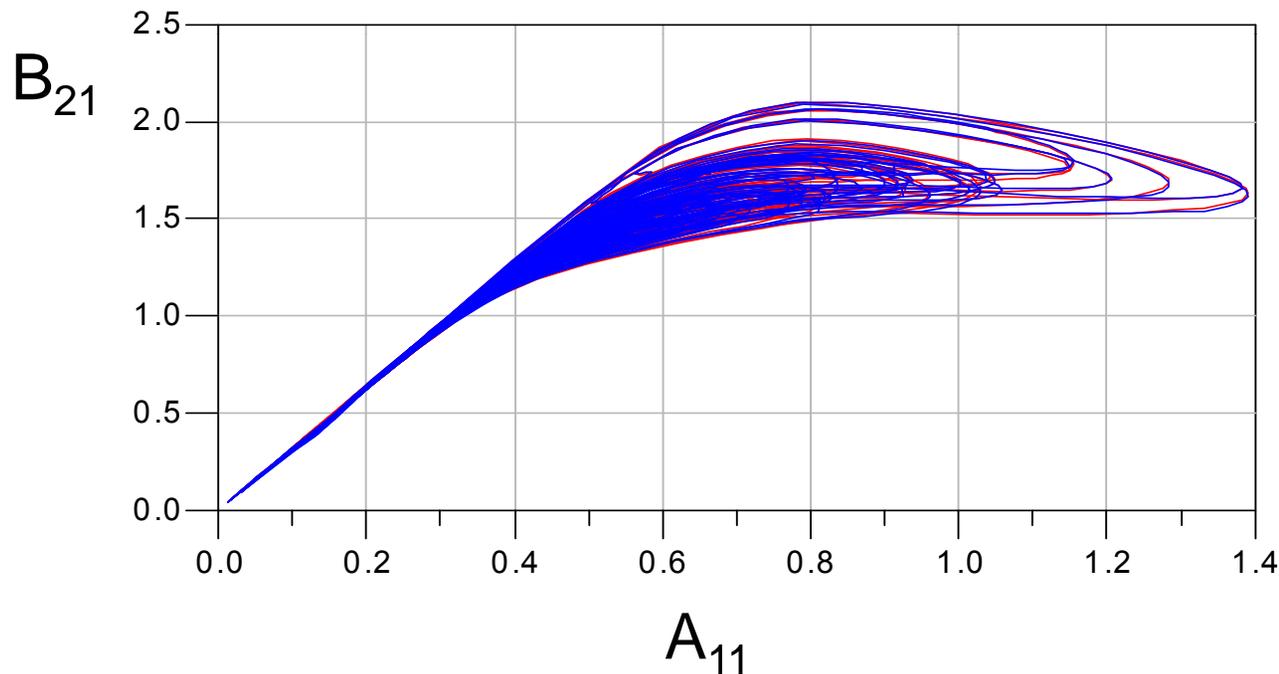
Pulsed RF signal at 1GHz:
Thermal Time Const. 10usec

Systematic approach to
identifying "hidden" state
variables for long-term
memory IMS2007 [13]

Dynamic Long-Term Memory PHD Models Envelope Differential Equations in ADS [7,8,13]

Verspecht et al in *2007 International Microwave Symposium Digest* [13]

X-parameters with dynamic memory (red)
compared to circuit-level model (blue)



Conclusions

Powerful nonlinear device & behavioral modeling approaches in time, frequency, and mixed domains have been presented

- X-parameters are mature. Commercial solutions to measure, model, and simulate are available, supported, and expanding (see lecture 2).
- Time-domain (NLTSA) techniques could become practical soon.
- Envelope domain (dynamic X-parameters) is attractive for memory.

Emergence of commercially available Large-Signal HW & SW

- e.g. NVNA on modern PNA-X platform [9,14]
- e.g. nonlinear simulators with built-in XnP components & X-param analysis

Great opportunity for applications

- Specification of active components by *X-parameters*
- Device and behavioral modeling applications of NVNA measurements
- Stability analysis and matching power amplifiers under drive
- Active Signal Integrity

References

- [1] J. Wood, D. E. Root, N. B. Tuffillaro, "A behavioral modeling approach to nonlinear model-order reduction for RF/microwave ICs and systems," *IEEE Transactions on Microwave Theory and Techniques*, Vol. 52, Issue 9, Part 2, Sept. 2004 pp. 2274-2284
- [2] Agilent HMMC-5200 DC-20 GHz HBT Series-Shunt Amplifier, Data Sheet, August 2002.
- [3] J. Verspecht, M. Vanden Bossche, F. Verbeyst, "Characterizing Components under Large Signal Excitation: Defining Sensible `Large Signal S-Parameters`?!", in *49th IEEE ARFTG Conference Dig.*, Denver, CO, USA, June 1997, pp. 109-117.
- [4] J. Verspecht, D.E. Root, J. Wood, A. Cognata, "Broad-Band, Multi-Harmonic Frequency Domain Behavioral Models from Automated Large-Signal Vectorial Network Measurements," in *2005 IEEE MTT-S International Microwave Symposium Digest*, Long Beach, CA, USA, June 2005.
- [5] D. E. Root, J. Verspecht, D. Sharrit, J. Wood, and A. Cognata, "Broad-Band Poly-Harmonic Distortion (PHD) Behavioral Models from Fast Automated Simulations and Large-Signal Vectorial Network Measurements", *IEEE Transactions on Microwave Theory and Techniques* Vol. 53. No. 11, November, 2005 pp. 3656-3664
- [6] J. Wood, D. E. Root, editors, **Fundamentals of Nonlinear Behavioral Modeling for RF and Microwave Design**, 1st ed. Norwood, MA, USA, Artech House, 2005.
- [7] Root et al US Patent Publication # US2005102124 AA, Published 2005
- [8] D. E. Root, D. Sharrit, J. Verspecht, "Nonlinear Behavioral Models with Memory: Formulation, Identification, and Implementation," *2006 IEEE MTT-S International Microwave Symposium Workshop (WSL) on Memory Effects in Power Amplifiers*
- [9] Blockley et al *2005 IEEE MTT-S International Microwave Symposium Digest*, Long Beach, CA, USA, June 2005.
- [10] Jan Verspecht Patent US 7,038,468 B2 (issued May 2, 2006 based on a provisional patent 60/477,349 filed on June 11, 2003)
- [11] Soury et al *2005 IEEE International Microwave Symposium Digest* pp. 975-978
- [12] J. Verspecht and D. E. Root, "Poly-Harmonic Distortion Modeling," in *IEEE Microwave Theory and Techniques Microwave Magazine*, June, 2006.
- [13] J. Verspecht, D. Gunyan, J. Horn, J. Xu, A. Cognata, and D.E. Root, "Multi-tone, Multi-Port, and Dynamic Memory Enhancements to PHD Nonlinear Behavioral Models from Large-Signal Measurements and Simulations," *2007 IEEE MTT-S Int. Microwave Symp. Dig.*, Honolulu, HI, USA, June 2007.
- [14] Horn et al 2008 Power Amplifier Symposium, Orlando, Jan. 2008